

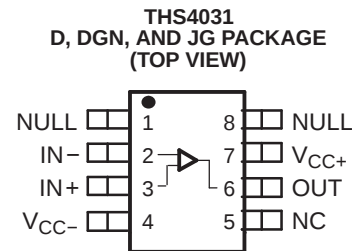
100-MHz LOW-NOISE HIGH-SPEED AMPLIFIERS

FEATURES

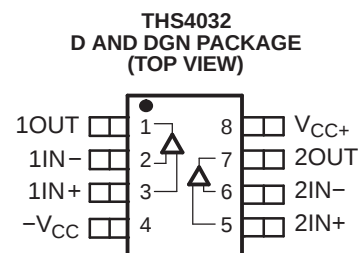
- **Ultralow $1.6\text{-nV}/\sqrt{\text{Hz}}$ Voltage Noise**
- **High Speed:**
 - 100-MHz Bandwidth [$G = 2$ (-1), -3 dB]
 - 100-V/ μs Slew Rate
- **Very Low Distortion**
 - THD = -72 dBc ($f = 1\text{ MHz}$, $R_L = 150\ \Omega$)
 - THD = -90 dBc ($f = 1\text{ MHz}$, $R_L = 1\text{ k}\Omega$)
- **Low 0.5-mV (Typ) Input Offset Voltage**
- **90-mA Output Current Drive (Typical)**
- **$\pm 5\text{ V}$ to $\pm 15\text{ V}$ Typical Operation**
- **Available in Standard SOIC, MSOP, PowerPAD™, JG, or FK Package**
- **Evaluation Module Available**

SUPPORTS DEFENSE, AEROSPACE, AND MEDICAL APPLICATIONS

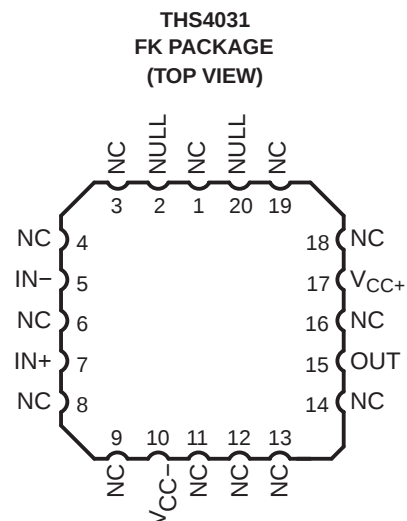
- **Controlled Baseline**
- **One Assembly/Test Site**
- **One Fabrication Site**
- **Available in Military ($-55^\circ\text{C}/125^\circ\text{C}$) Temperature Range⁽¹⁾**
- **Extended Product Life Cycle**
- **Extended Product-Change Notification**
- **Product Traceability**



NC – No internal connection



Cross-Section View Showing
PowerPAD™ Option (DGN)



(1) Additional temperature ranges are available - contact factory

RELATED DEVICES

DEVICE	DESCRIPTION
THS4051/2	70-MHz High-Speed Amplifiers
THS4081/2	175-MHz Low Power High-Speed Amplifiers



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

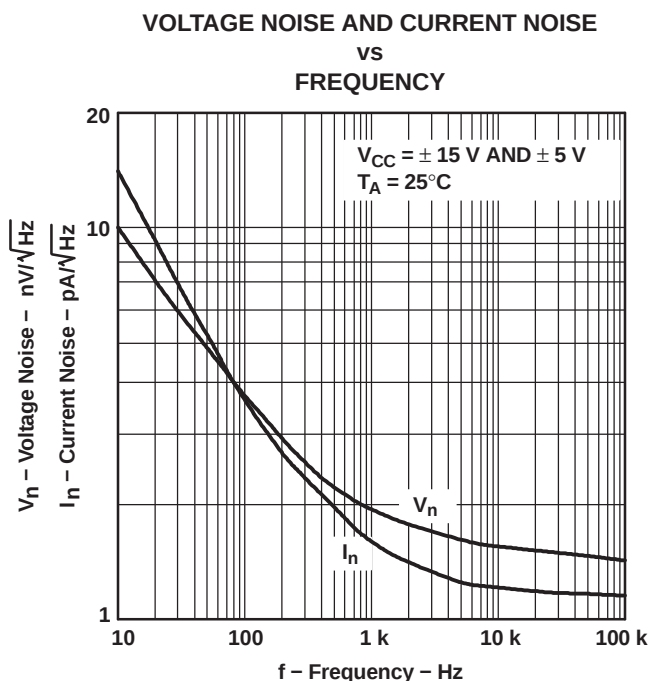
PowerPAD is a trademark of Texas Instruments.



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

DESCRIPTION

The THS4031 and THS4032 are ultralow-voltage noise, high-speed voltage feedback amplifiers that are ideal for applications requiring low voltage noise, including communications and imaging. The single amplifier THS4031 and the dual amplifier THS4032 offer very good ac performance with 100-MHz bandwidth ($G = 2$), 100-V/ μ s slew rate, and 60-ns settling time (0.1%). The THS4031 and THS4032 are unity gain stable with 275-MHz bandwidth. These amplifiers have a high drive capability of 90 mA and draw only 8.5-mA supply current per channel. With -90 dBc of total harmonic distortion (THD) at $f = 1$ MHz and a very low noise of 1.6 nV/ $\sqrt{\text{Hz}}$, the THS4031 and THS4032 are ideally suited for applications requiring low distortion and low noise such as buffering analog-to-digital converters.



ORDERING INFORMATION⁽¹⁾

T_A	PACKAGE ⁽²⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
-55°C to 125°C	MSOP-PowerPAD	THS4032MDGNREP	NXX

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

FUNCTIONAL BLOCK DIAGRAMS

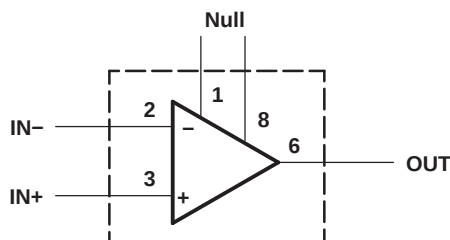


Figure 1. THS4031 – Single Channel

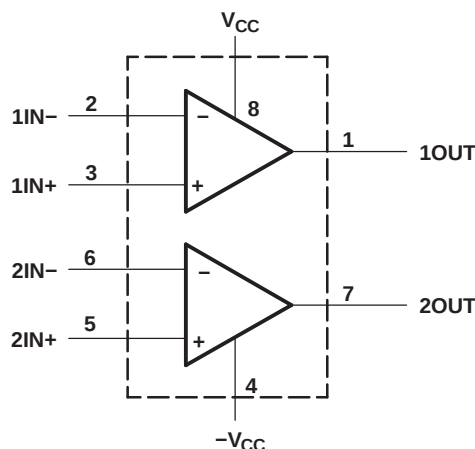


Figure 2. THS4032 – Dual Channel

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Over operating free-air temperature range (unless otherwise noted).

		VALUE	UNIT
V_{CC}	Supply voltage, V_{CC+} to V_{CC-}	33	V
V_I	Input voltage	$\pm V_{CC}$	
I_O	Output current	150	mA
V_{IO}	Differential input voltage	± 4	V
	Continuous total power dissipation	See Dissipation Ratings Table	
T_A	Operating free-air temperature	–55 to 125	°C
T_J	Maximum junction temperature, (any condition)	150	°C
	Maximum junction temperature, continuous operation, long term reliability ⁽²⁾	130	°C
T_{stg}	Storage temperature ⁽³⁾	–65 to 150	°C
	Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	300	°C
	Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds, JG package	300	°C
	Case temperature for 60 seconds, FK package	260	°C

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The maximum junction temperature for continuous operation is limited by package constraints. Operation above this temperature may result in reduced reliability and/or lifetime of the device. Does not apply to the JG package or FK package.
- (3) Long-term high-temperature storage and/or extended use at maximum recommended operating conditions may result in a reduction of overall device life. See http://www.ti.com/ep_quality for additional information on enhanced plastic packaging.

DISSIPATION RATINGS TABLE

PACKAGE	θ_{JA} (°C/W)	θ_{JC} (°C/W)	$T_A = 25^\circ\text{C}$ POWER RATING
D	167 ⁽¹⁾	38.3	629 mW, $T_J = 130^\circ\text{C}$, continuous
DGN ⁽²⁾	58.4	4.7	1.8 W, $T_J = 130^\circ\text{C}$, continuous
JG	119	28	1050 mW, $T_J = 150^\circ\text{C}$, continuous
FK	87.7	20	1375 mW, $T_J = 150^\circ\text{C}$, continuous

- (1) This data was taken using the JEDEC standard Low-K test PCB. For the JEDEC Proposed High-K test PCB, the θ_{JA} is 95°C/W with a power rating at $T_A = 25^\circ\text{C}$ of 1.32 W.
- (2) This data was taken using 2 oz. trace and copper pad that is soldered directly to a 3-in × 3-in PCB. For further information, refer to *Application Information* section of this data sheet.

RECOMMENDED OPERATING CONDITIONS

		MIN	MAX	UNIT
V_{CC+} and V_{CC-}	Supply voltage	±4.5	±16	V
	Dual supply			
	Single supply	9	32	
T_A	Operating free-air temperature	–55	125	°C

ELECTRICAL CHARACTERISTICS

At T_A = full range, $V_{CC} = \pm 15$ V, and $R_L = 1$ k Ω (unless otherwise noted).

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT		
DYNAMIC PERFORMANCE									
BW	Small-signal bandwidth (–3 dB)	V _{CC} = ±15 V		Gain = –1 or 2	100		MHz		
		V _{CC} = ±5 V			90				
	Bandwidth for 0.1-dB flatness	V _{CC} = ±15 V		Gain = –1 or 2	50		MHz		
		V _{CC} = ±5 V			45				
	Full power bandwidth ⁽¹⁾	V _{O(pp)} = 20 V, V _{CC} = ±15 V		R _L = 1 kΩ	2.3		MHz		
V _{O(pp)} = 5 V, V _{CC} = ±5 V		7.1							
SR	Slew rate ⁽²⁾	V _{CC} = ±15 V		R _L = 1 kΩ	100		V/μs		
t _s	Settling time to 0.1%	V _{CC} = ±15 V, 5-V step		Gain = –1	60		ns		
		V _{CC} = ±5 V, 2.5-V step			45				
	Settling time to 0.01%	V _{CC} = ±15 V, 5-V step		Gain = –1	90		ns		
		V _{CC} = ±5 V, 2.5-V step			80				
NOISE/DISTORTION PERFORMANCE									
THD	Total harmonic distortion	V _{CC} = ±5 V or ±15 V, f = 1 MHz, Gain = 2, V _{O(pp)} = 2 V, T _A = 25°C		R _L = 150 Ω	–81		dBc		
				R _L = 1 kΩ	–96				
V _n	Input voltage noise	V _{CC} = ±5 V or ±15 V, T _A = 25°C f > 10 kHz		R _L = 150 Ω	1.6		nA/√Hz		
I _n	Input current noise	V _{CC} = ±5 V or ±15 V, T _A = 25°C f > 10 kHz		R _L = 150 Ω	1.2		pA/√Hz		
	Differential gain error	Gain = 2, 40 IRE modulation, T _A = 25°C NTSC and PAL, ±100 IRE ramp, R _L = 150 Ω		V _{CC} = ±15 V	0.015%		°		
	V _{CC} = ±5 V			0.02%					
Differential phase error				V _{CC} = ±15 V	0.025				
				V _{CC} = ±5 V	0.03				
DC PERFORMANCE									
Open loop gain		V _{CC} = ±15 V, R _L = 1 kΩ, V _O = ±10 V		T _A = 25°C	93	98	dB		
				T _A = full range		92			
				V _{CC} = ±5 V, R _L = 1 kΩ, V _O = ±2.5 V		T _A = 25°C		92	95
						T _A = full range		91	
V _{IO}	Input offset voltage	V _{CC} = ±5 V or ±15 V		T _A = 25°C	0.5	2	mV		
				T _A = full range		3			
I _{IB}	Input bias current	V _{CC} = ±5 V or ±15 V		T _A = 25°C	3	6	μA		
				T _A = full range		8			
I _{IO}	Input offset current	V _{CC} = ±5 V or ±15 V		T _A = 25°C	30	250	nA		
				T _A = full range		450			
	Offset voltage drift	V _{CC} = ±5 V or ±15 V		T _A = full range	2		μV/°C		
	Input offset current drift	V _{CC} = ±5 V or ±15 V		T _A = full range	0.2		nA/°C		

(1) Full power bandwidth = slew rate / $[\sqrt{2} \pi V_{OC(peak)}]$.

(2) Slew rate is measured from an output level range of 25% to 75%.

ELECTRICAL CHARACTERISTICS (continued)

At T_A = full range, $V_{CC} = \pm 15$ V, and $R_L = 1$ k Ω (unless otherwise noted).

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
INPUT CHARACTERISTICS							
V _{ICR}	Common-mode input voltage range	V _{CC} = ±15 V		±13.5	±14.3		V
		V _{CC} = ±5 V		±3.6	±4.3		
CMRR	Common-mode rejection ratio	V _{CC} = ±15 V, V _{ICR} = ±12 V	T _A = 25°C	85	95		dB
			T _A = full range	80			
		V _{CC} = ±5 V, V _{ICR} = ±2.5 V	T _A = 25°C	90	100		
			T _A = full range	85			
r _i	Input resistance				2		MΩ
C _i	Input capacitance				1.5		pF
OUTPUT CHARACTERISTICS							
V _O	Output voltage swing	V _{CC} = ±15 V	R _L = 1 kΩ	±13	±13.6		V
		V _{CC} = ±5 V		±3.4	±3.8		
		V _{CC} = ±15 V	R _L = 150 Ω	±12	±12.9		
		V _{CC} = ±5 V	R _L = 250 Ω	±3	±3.5		
I _O	Output current ⁽³⁾	V _{CC} = ±15 V	R _L = 20 Ω	60	90		mA
		V _{CC} = ±5 V		50	70		
I _{SC}	Short-circuit current ⁽³⁾	V _{CC} = ±15 V			150		mA
R _O	Output resistance	Open loop			13		Ω
POWER SUPPLY							
V _{CC}	Supply voltage operating range	Dual supply			±4.5	±16.5	V
		Single supply			9	33	
I _{CC}	Supply current (each amplifier)	V _{CC} = ±15 V	T _A = 25°C	8.5	10		mA
			T _A = full range		11		
		V _{CC} = ±5 V	T _A = 25°C	7.5	9		
			T _A = full range		10		
PSRR	Power-supply rejection ratio	V _{CC} = ±5 V or ±15 V	T _A = 25°C	85	95		dB
			T _A = full range	80			

(3) Observe power dissipation ratings to keep the junction temperature below the absolute maximum rating when the output is heavily loaded or shorted. See the [Absolute Maximum Ratings table](#) in this data sheet for more information.

PARAMETER MEASUREMENT INFORMATION

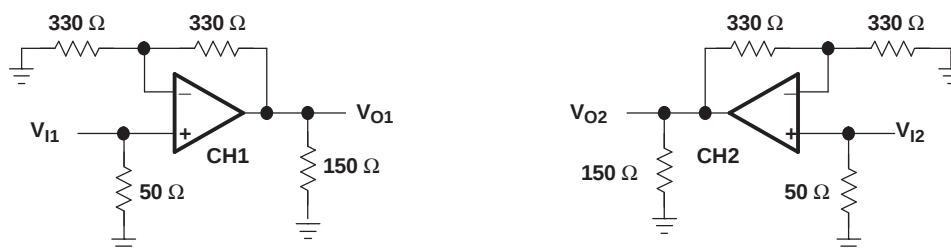


Figure 3. THS4032 Crosstalk Test Circuit

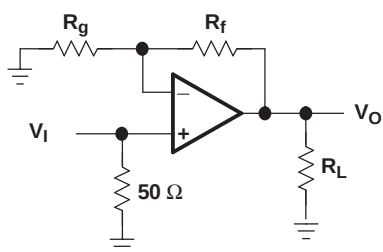


Figure 4. Step Response Test Circuit

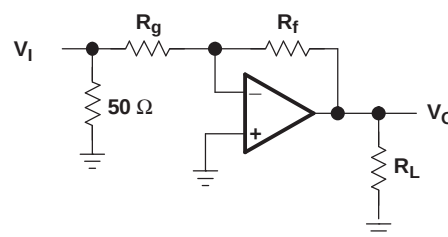


Figure 5. Step Response Test Circuit

TYPICAL CHARACTERISTICS

Table of Graphs

		FIGURE
Input offset voltage distribution		6, 7
Input offset voltage	vs Free-air temperature	8
Input bias current	vs Free-air temperature	9
Output voltage swing	vs Supply voltage	10
Maximum output voltage swing	vs Free-air temperature	11
Maximum output current	vs Free-air temperature	12
Supply current	vs Free-air temperature	13
Common-mode input voltage	vs Supply voltage	14
Closed-loop output impedance	vs Frequency	15
Open-loop gain and phase response	vs Frequency	16
Power-supply rejection ratio	vs Frequency	17
Common-mode rejection ratio	vs Frequency	18
Crosstalk	vs Frequency	19
Harmonic distortion	vs Frequency	20, 21
Harmonic distortion	vs Peak-to-peak output voltage	22, 23
Slew rate	vs Free-air temperature	24
0.1% settling time	vs Output voltage step size	25
Small signal frequency response with varying feedback resistance	Gain = 1, $V_{CC} = \pm 15V$, $R_L = 1k\Omega$	26
Frequency response with varying output voltage swing	Gain = 1, $V_{CC} = \pm 15V$, $R_L = 1k\Omega$	27
Small signal frequency response with varying feedback resistance	Gain = 1, $V_{CC} = \pm 15V$, $R_L = 150k\Omega$	28
Frequency response with varying output voltage swing	Gain = 1, $V_{CC} = \pm 15V$, $R_L = 150k\Omega$	29
Small signal frequency response with varying feedback resistance	Gain = 1, $V_{CC} = \pm 5V$, $R_L = 1k\Omega$	30
Frequency response with varying output voltage swing	Gain = 1, $V_{CC} = \pm 5V$, $R_L = 1k\Omega$	31
Small signal frequency response with varying feedback resistance	Gain = 1, $V_{CC} = \pm 5V$, $R_L = 150k\Omega$	32
Frequency response with varying output voltage swing	Gain = 1, $V_{CC} = \pm 5V$, $R_L = 150k\Omega$	33
Small signal frequency response with varying feedback resistance	Gain = 2, $V_{CC} = \pm 5V$, $R_L = 150k\Omega$	34
Small signal frequency response with varying feedback resistance	Gain = 2, $V_{CC} = \pm 5V$, $R_L = 150k\Omega$	35
Small signal frequency response with varying feedback resistance	Gain = -1, $V_{CC} = \pm 15V$, $R_L = 150k\Omega$	36
Frequency response with varying output voltage swing	Gain = -1, $V_{CC} = \pm 5V$, $R_L = 150k\Omega$	37
Small signal frequency response	Gain = 5, $V_{CC} = \pm 15V$, $\pm 5V$	38
Output amplitude	vs Frequency, Gain = 2, $V_S = \pm 15V$	39
Output amplitude	vs Frequency, Gain = 2, $V_S = \pm 5V$	40
Output amplitude	vs Frequency, Gain = -1, $V_S = \pm 15V$	41
Output amplitude	vs Frequency, Gain = -1, $V_S = \pm 5V$	42
Differential phase	vs Number of 150- Ω loads	43, 44
Differential gain	vs Number of 150- Ω loads	45, 46
1-V step response	vs Time	47, 48
4-V step response	vs Time	49
20-V step response	vs Time	50

TYPICAL CHARACTERISTICS

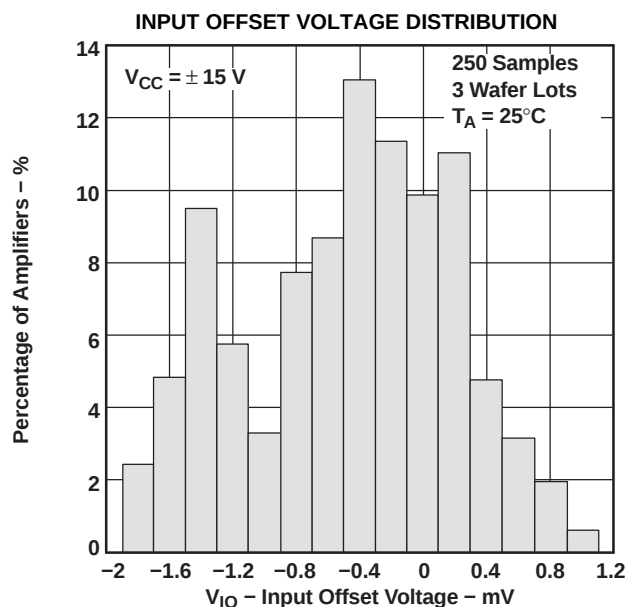


Figure 6.

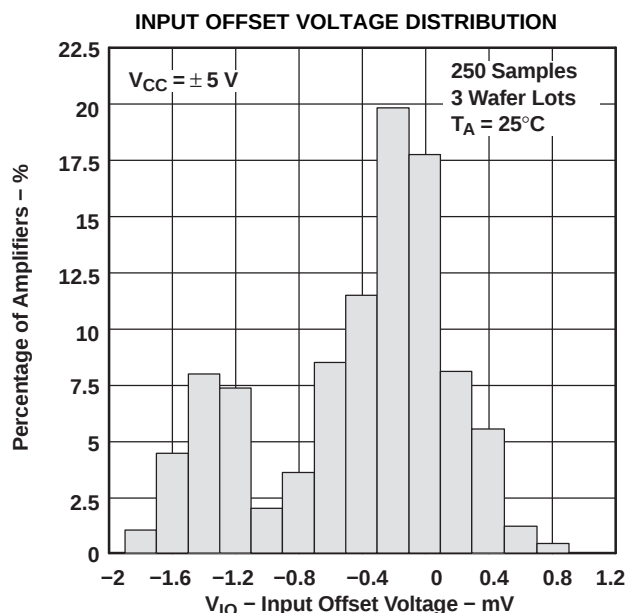


Figure 7.

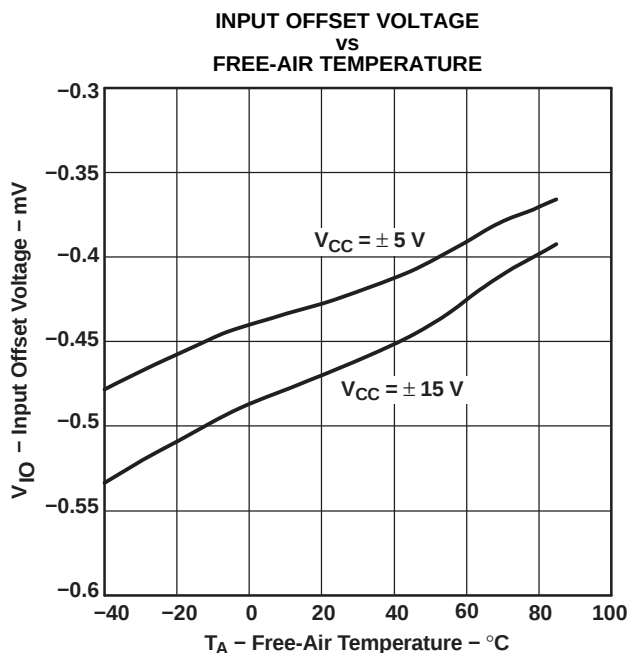


Figure 8.

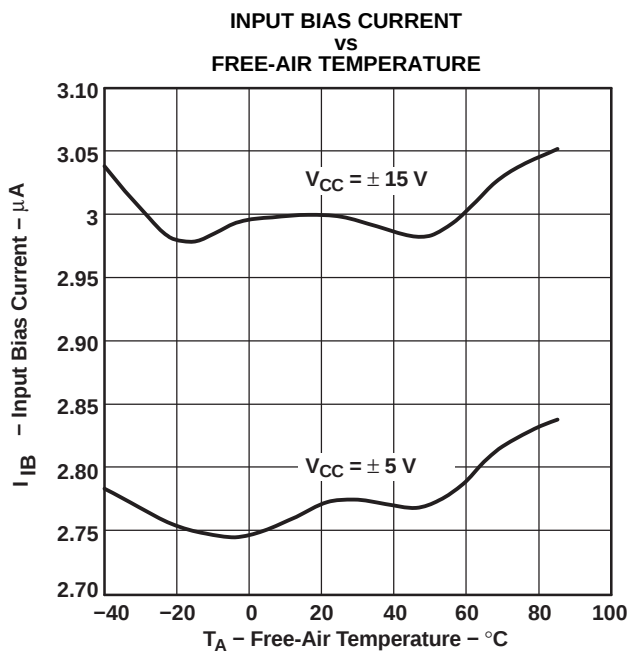


Figure 9.

TYPICAL CHARACTERISTICS (continued)

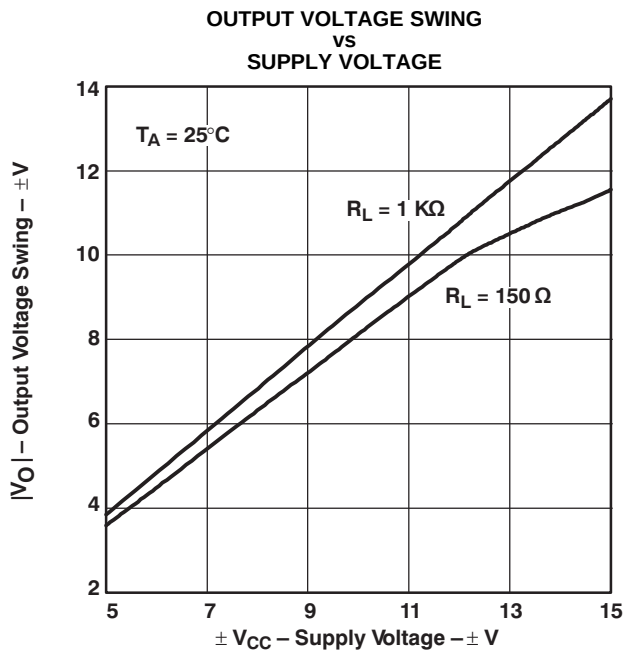


Figure 10.

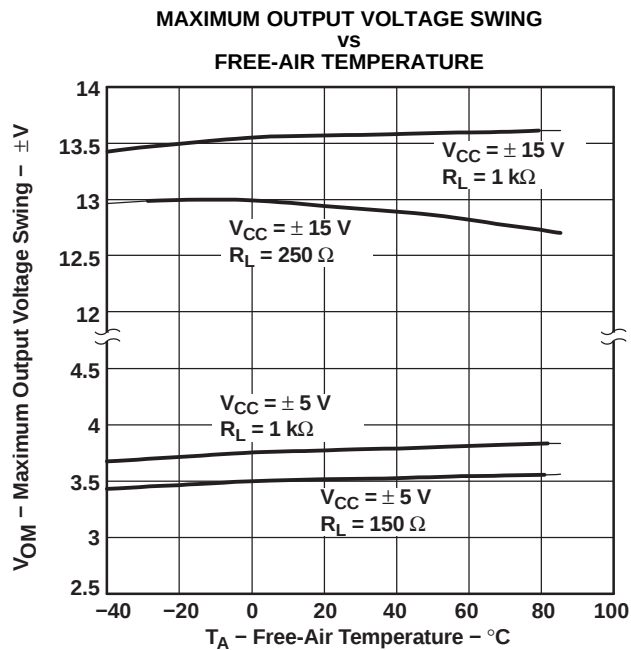


Figure 11.

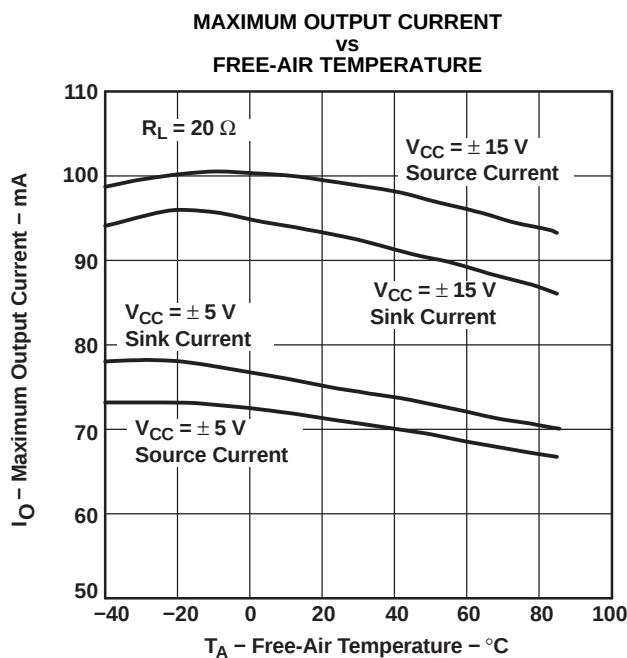


Figure 12.

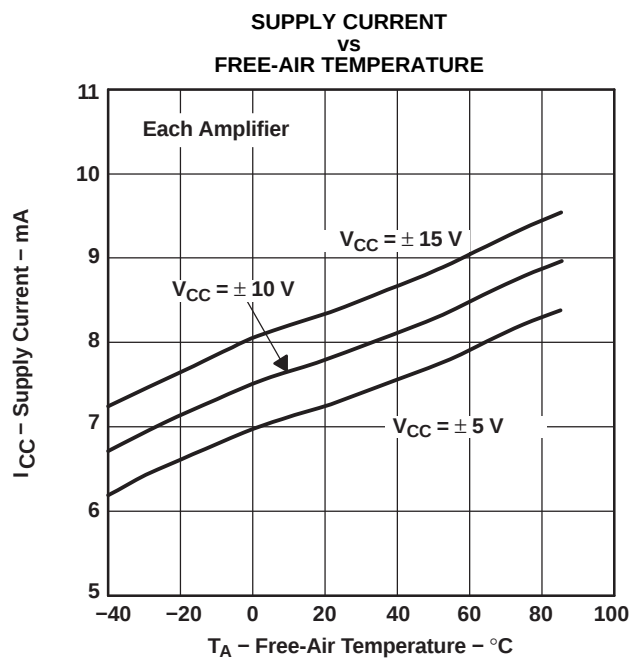


Figure 13.

TYPICAL CHARACTERISTICS (continued)

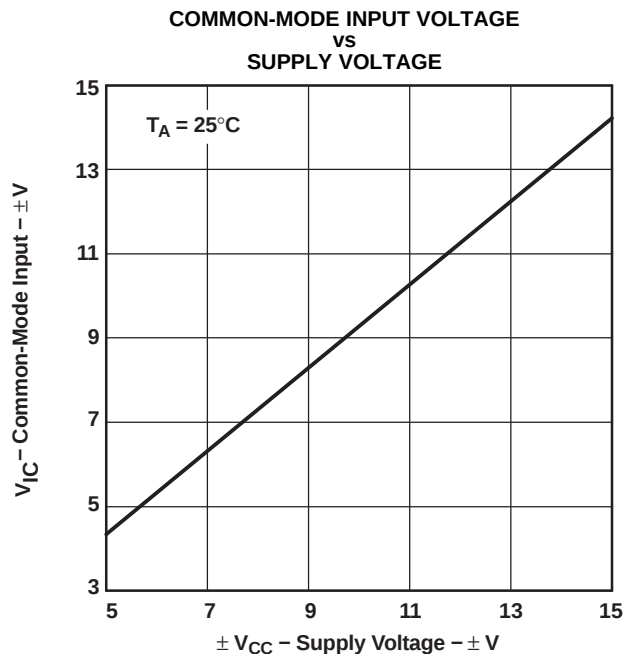


Figure 14.

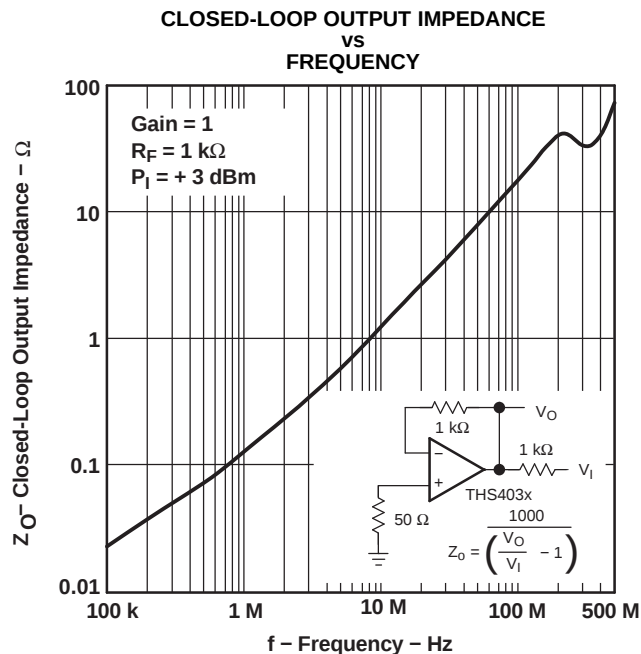


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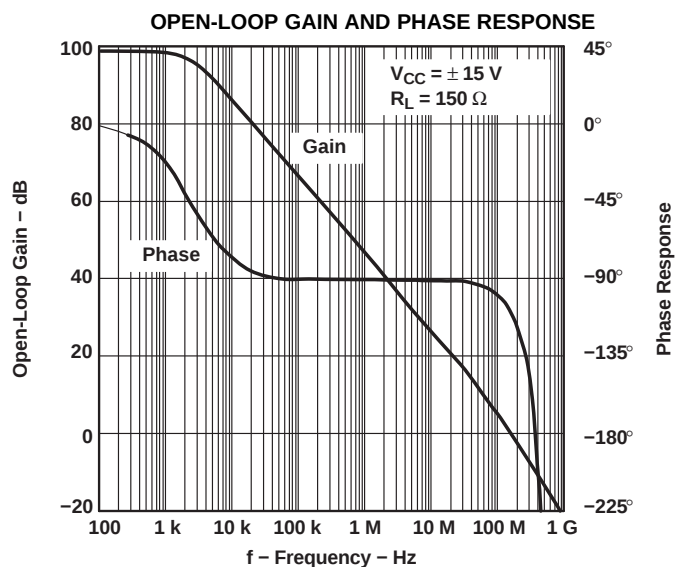


Figure 16.

TYPICAL CHARACTERISTICS (continued)

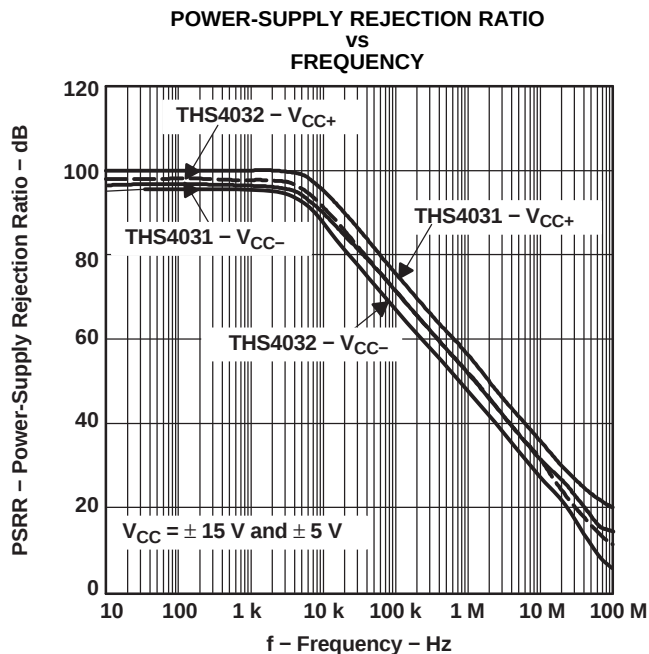


Figure 17.

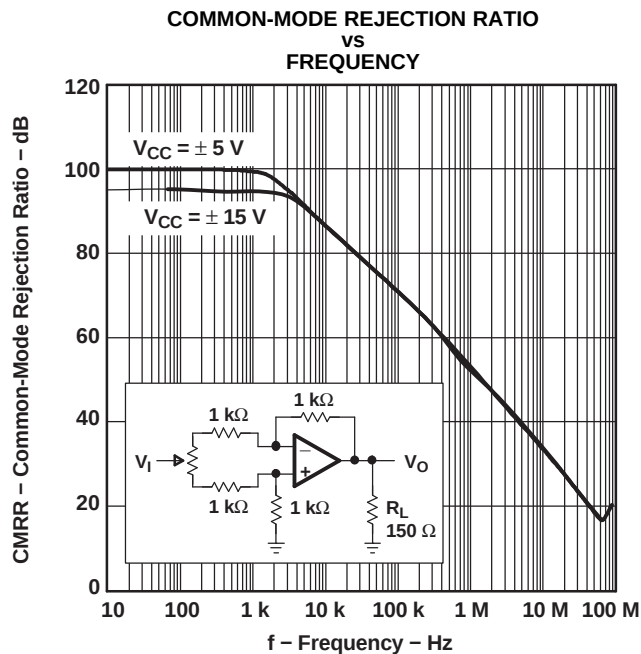


Figure 18.

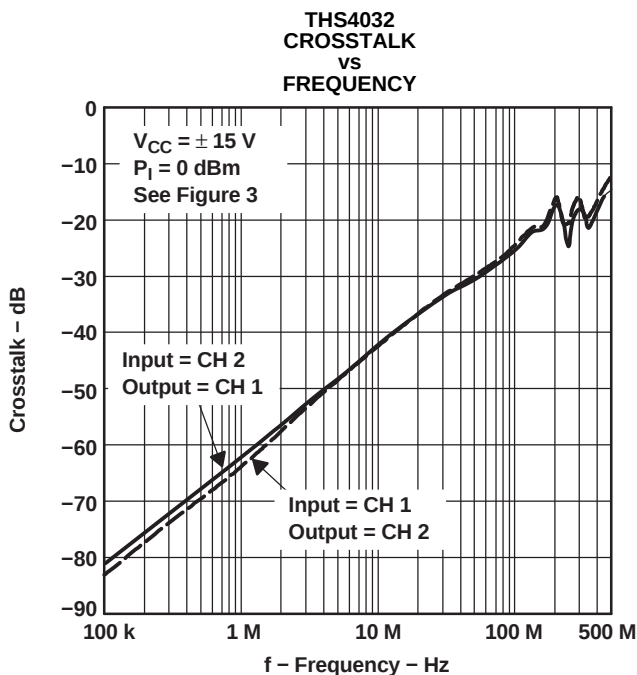


Figure 19.

TYPICAL CHARACTERISTICS (continued)

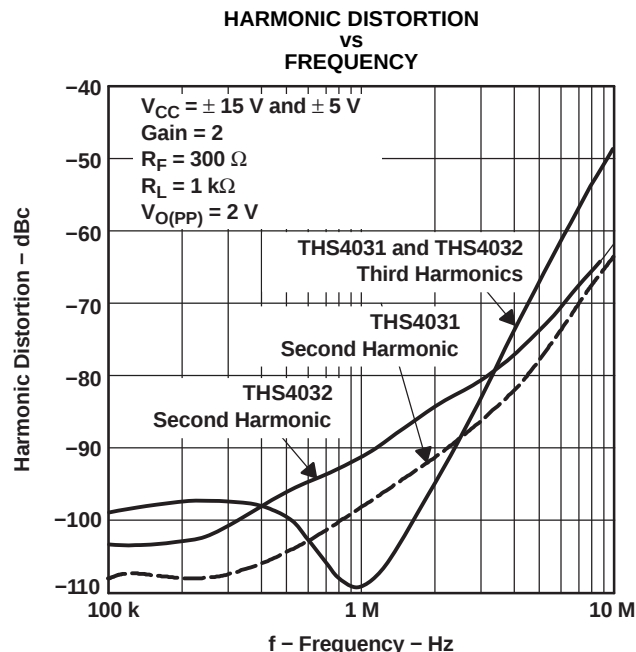


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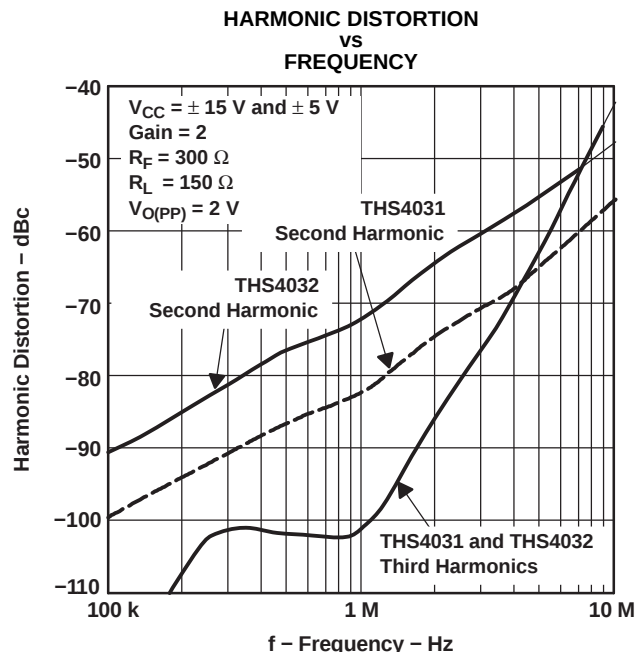


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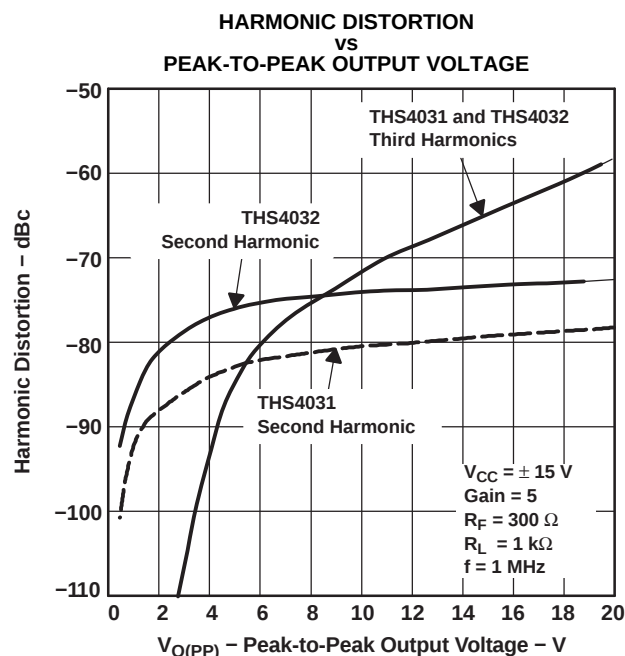


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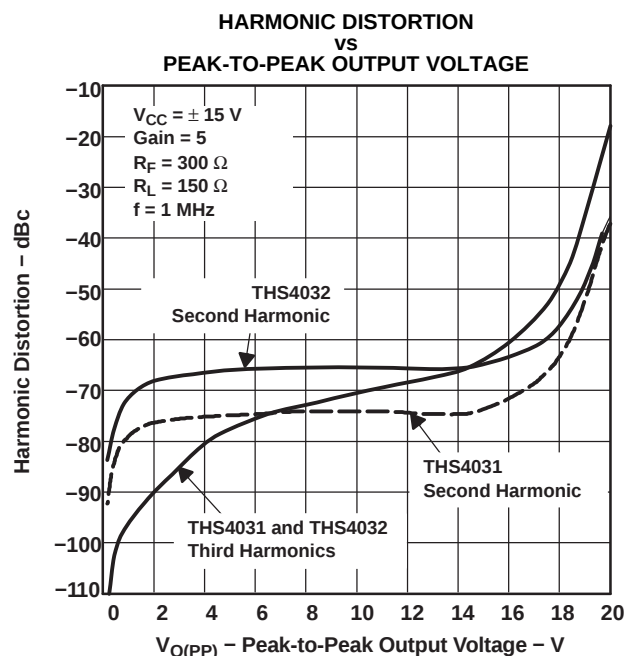


Figure 23.

TYPICAL CHARACTERISTICS (continued)

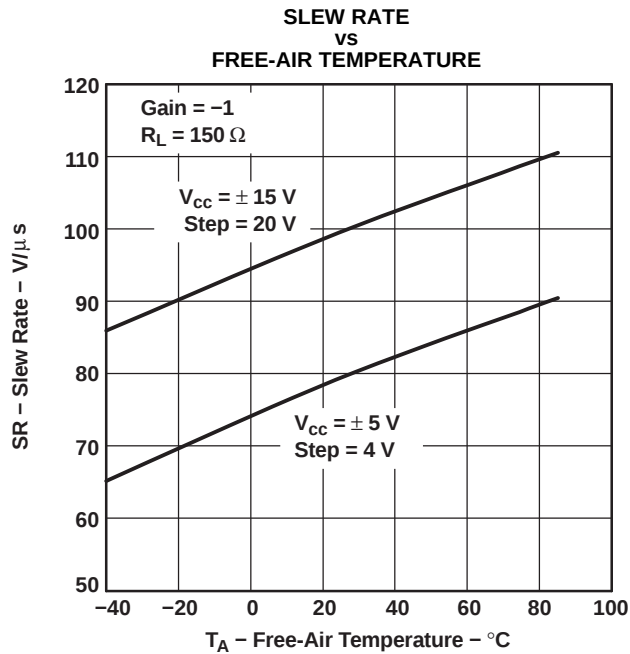


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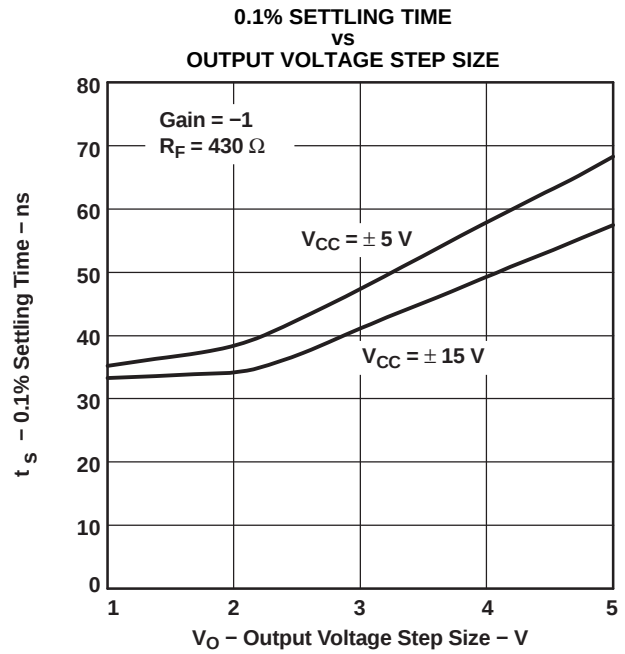


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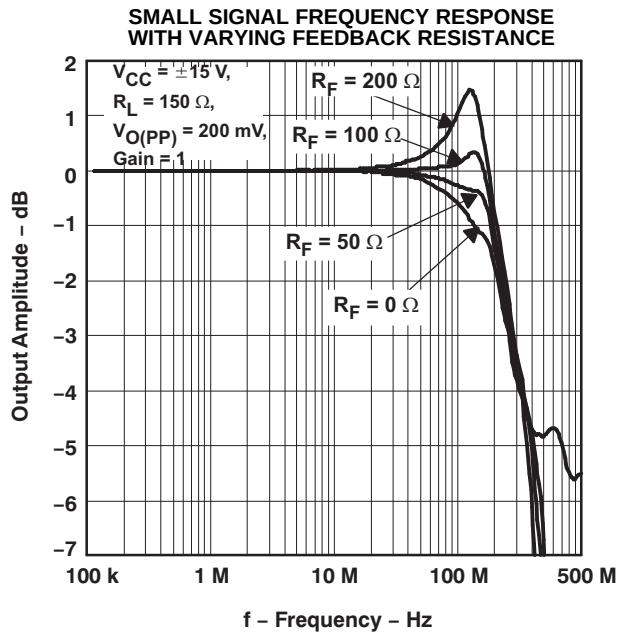


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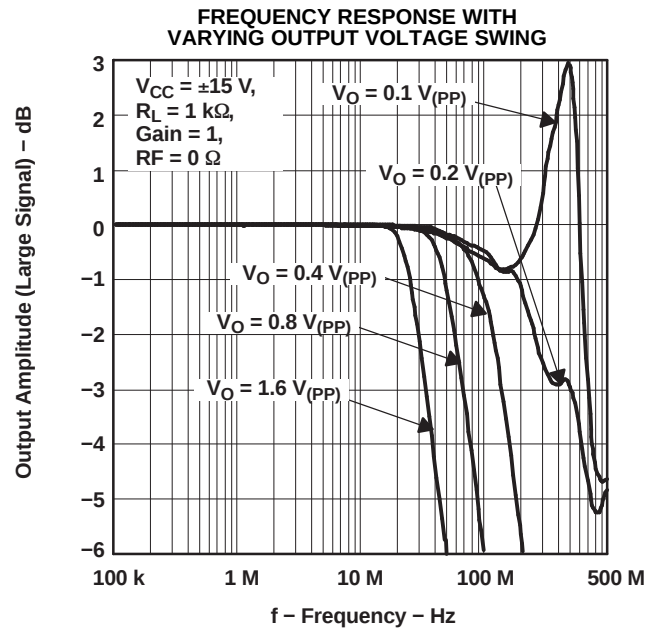


Figure 27.

TYPICAL CHARACTERISTICS (continued)

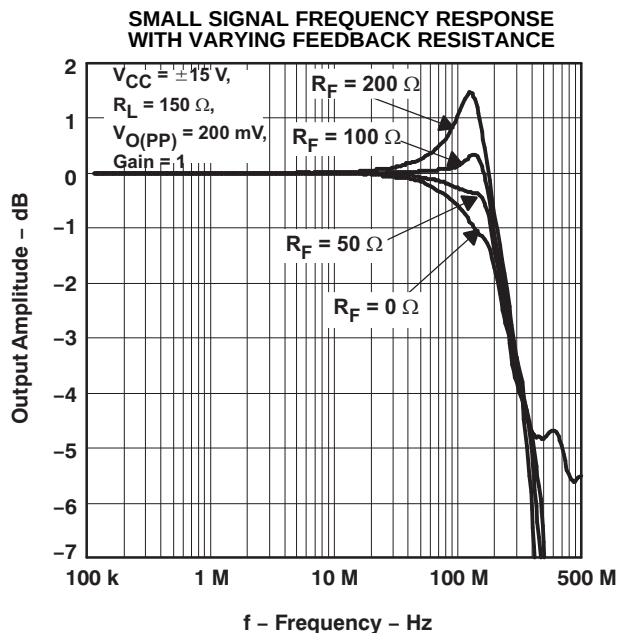


Figure 28.

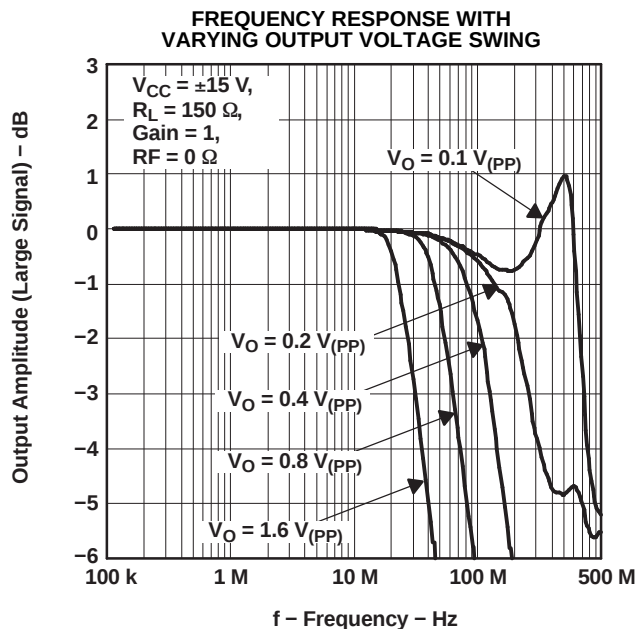


Figure 29.

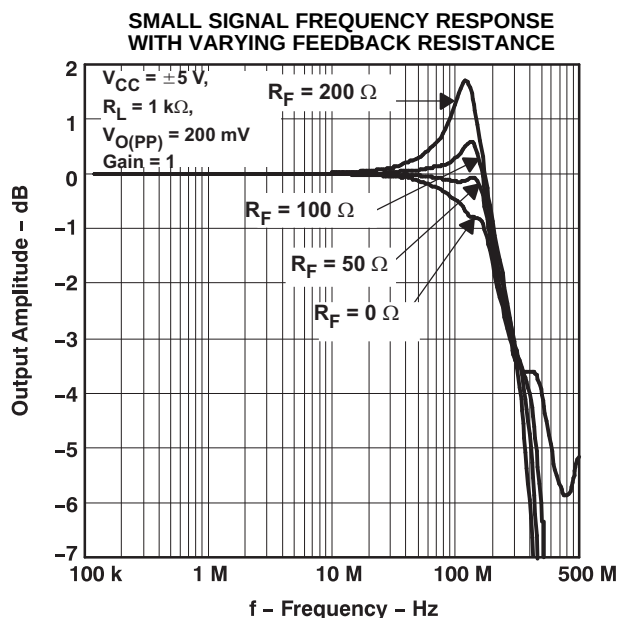


Figure 30.

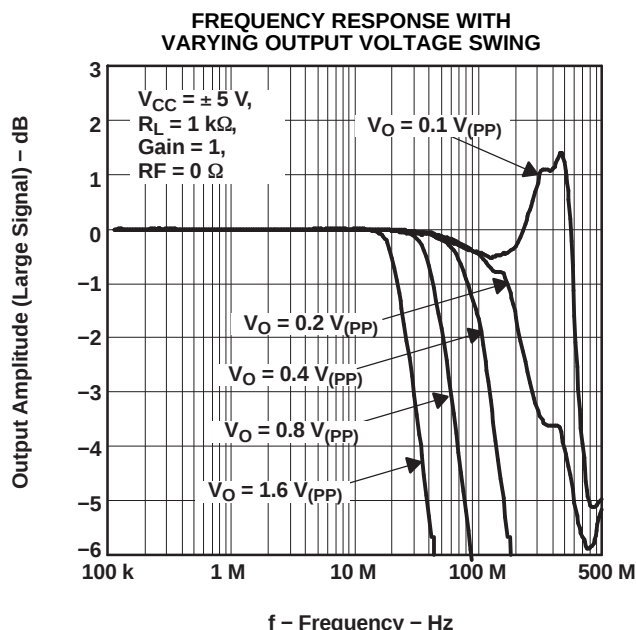


Figure 31.

TYPICAL CHARACTERISTICS (continued)

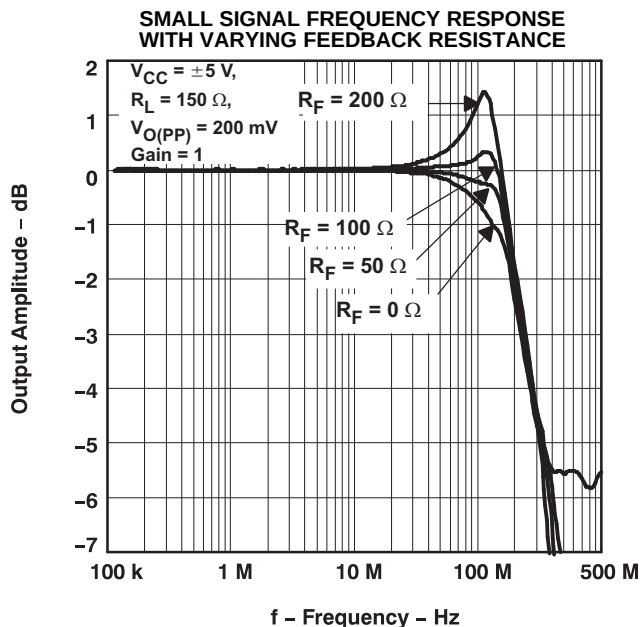


Figure 32.

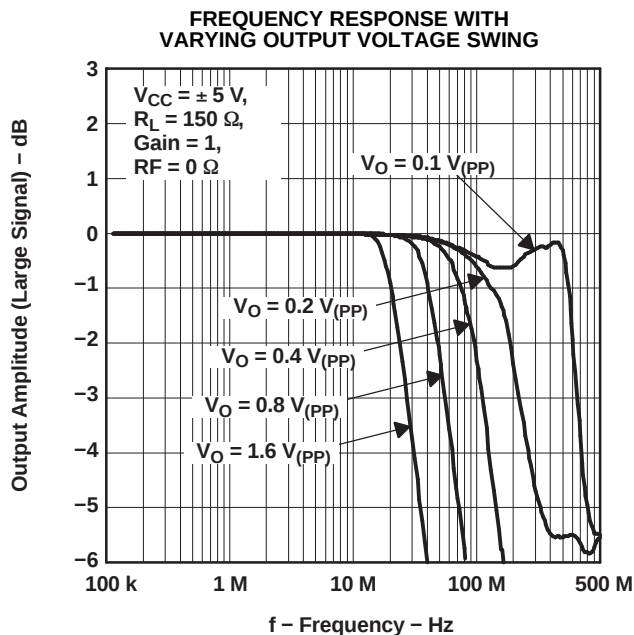


Figure 33.

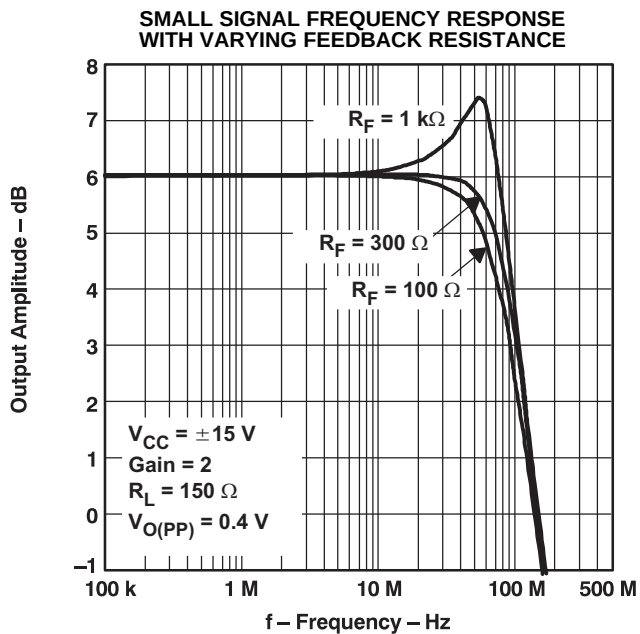


Figure 34.

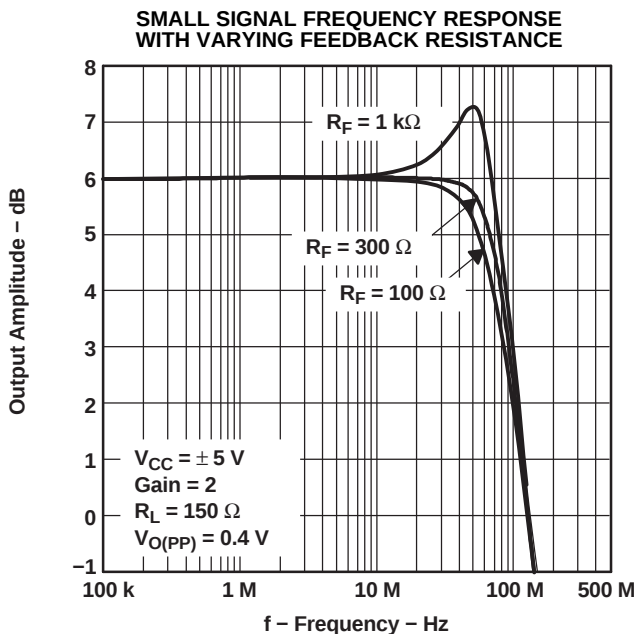


Figure 35.

TYPICAL CHARACTERISTICS (continued)

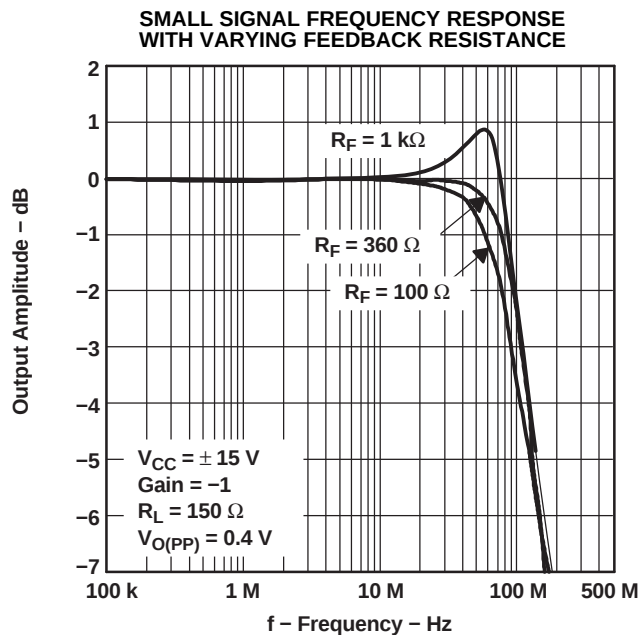


Figure 36.

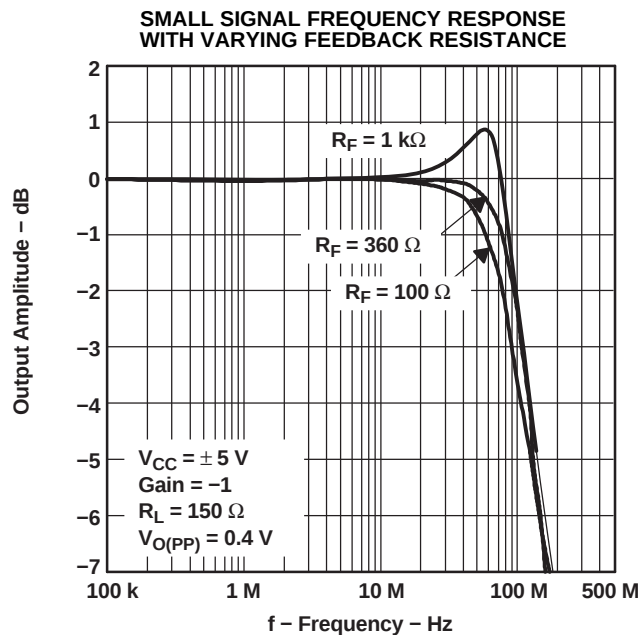


Figure 37.

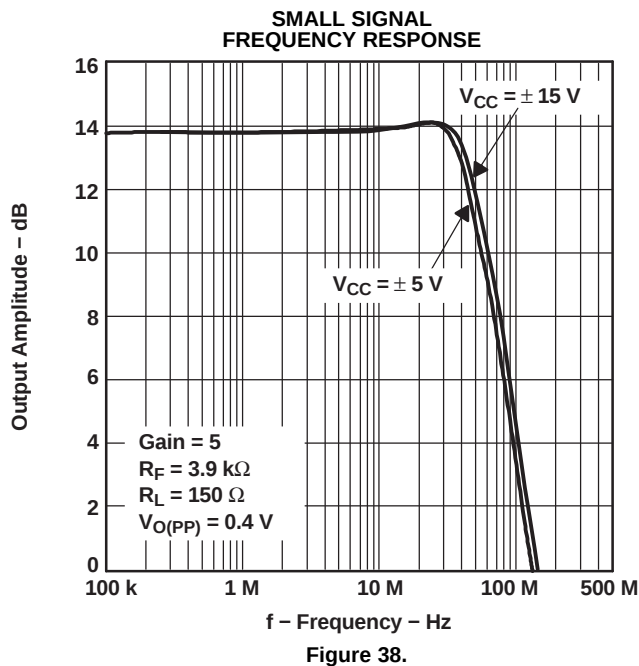


Figure 38.

TYPICAL CHARACTERISTICS (continued)

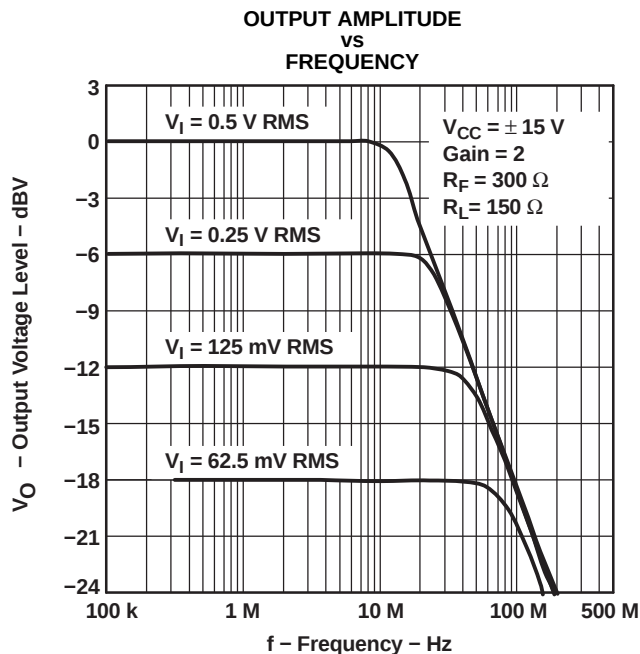


Figure 39.

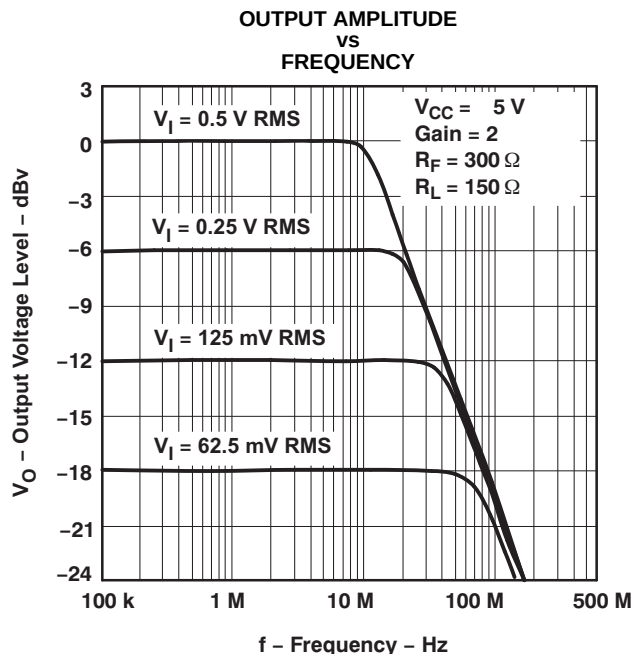


Figure 40.

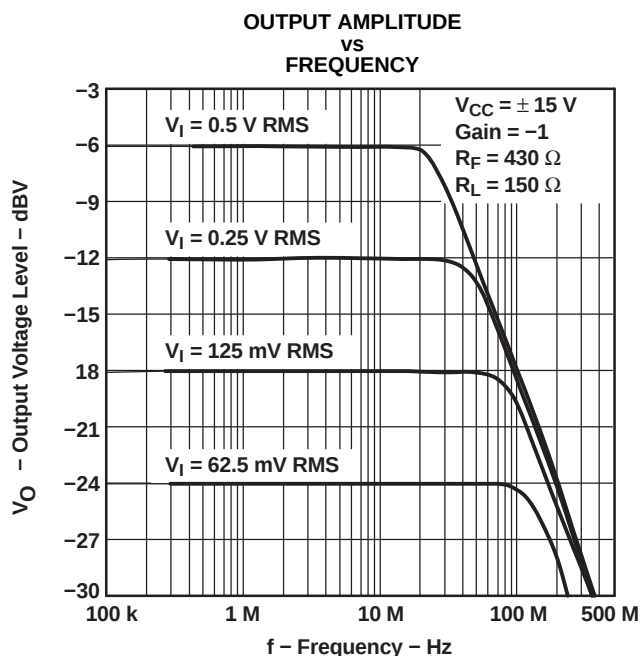


Figure 41.

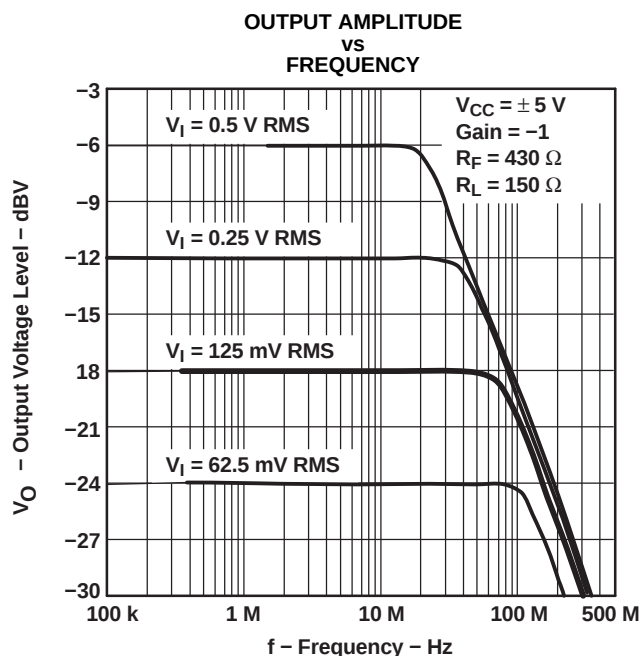


Figure 42.

TYPICAL CHARACTERISTICS (continued)

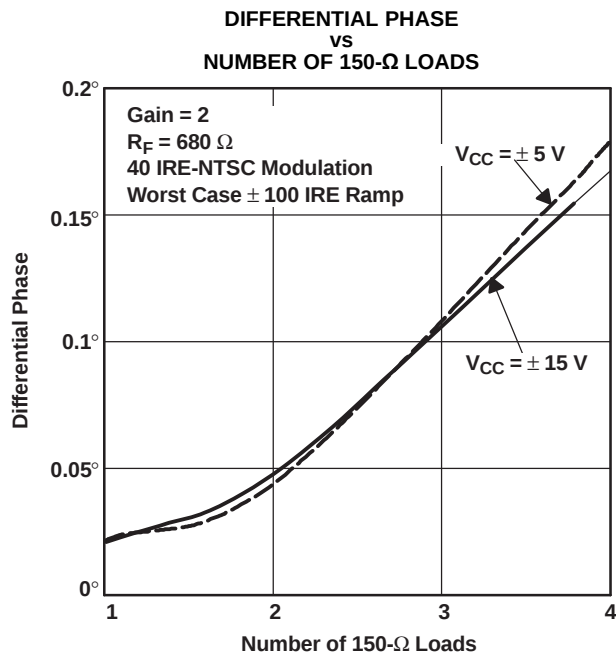


Figure 43.

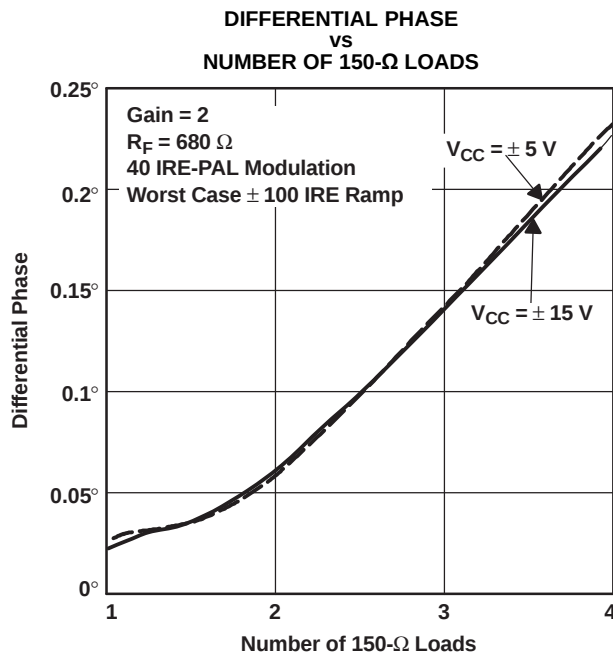


Figure 44.

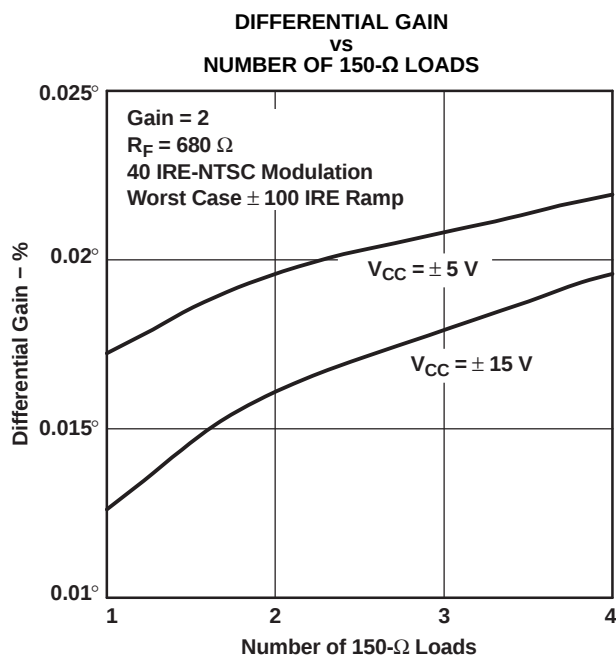


Figure 45.

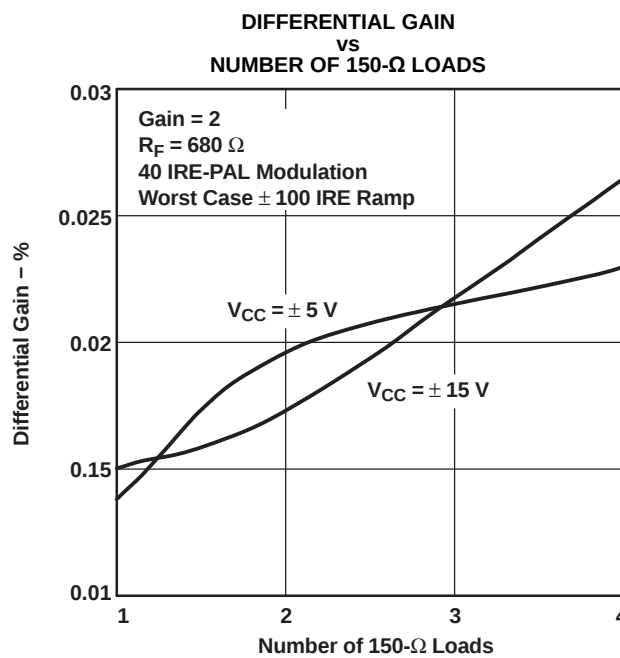
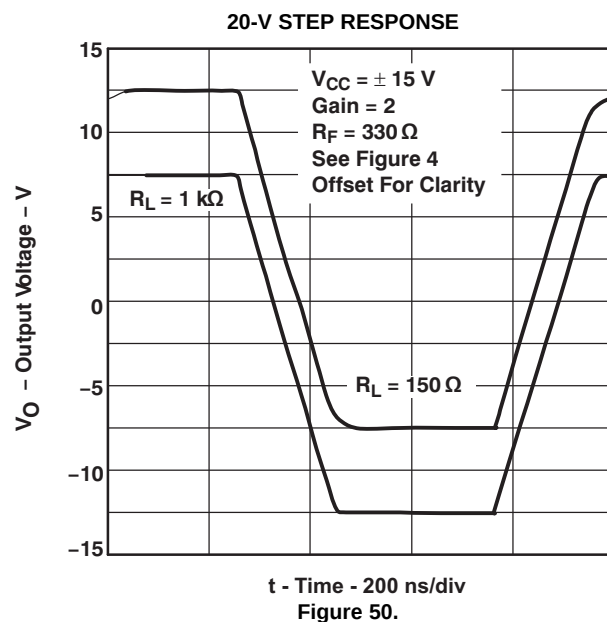
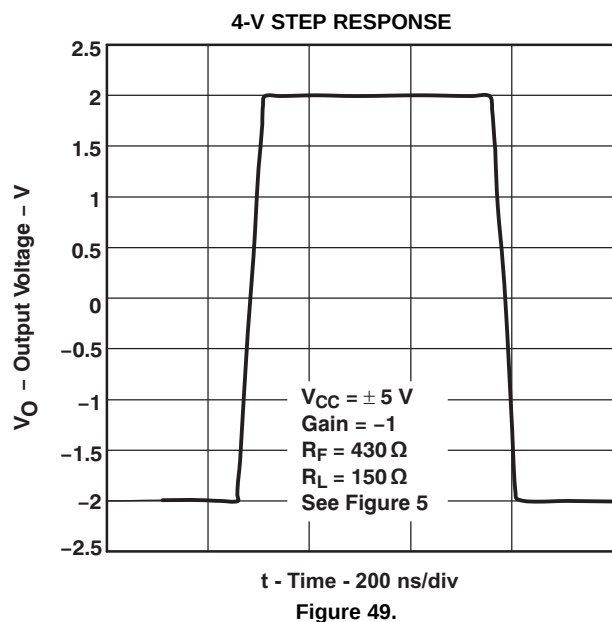
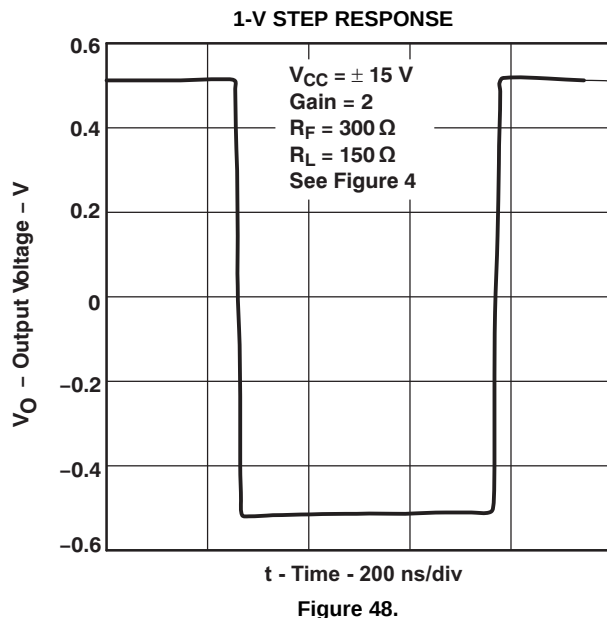
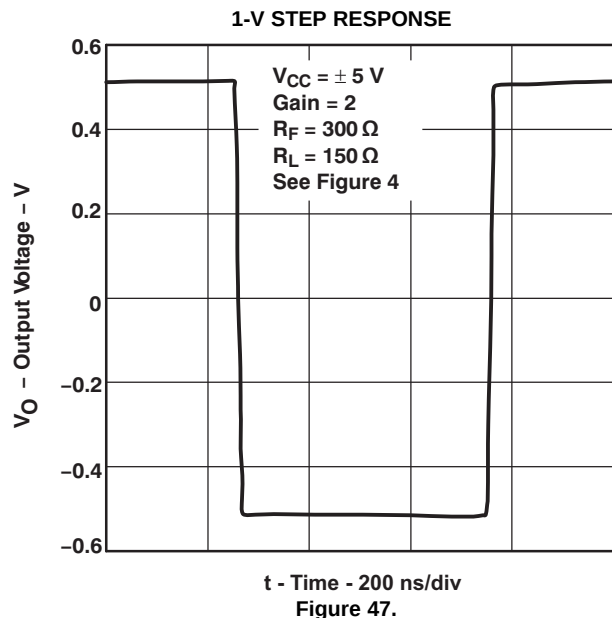


Figure 46.

TYPICAL CHARACTERISTICS (continued)



APPLICATION INFORMATION

THEORY OF OPERATION

The THS403x is a high-speed operational amplifier configured in a voltage feedback architecture. It is built using a 30-V, dielectrically isolated, complementary bipolar process with NPN and PNP transistors possessing f_T s of several GHz. This results in an exceptionally high-performance amplifier that has wide bandwidth, high slew rate, fast settling time, and low distortion. A simplified schematic is shown in [Figure 51](#).

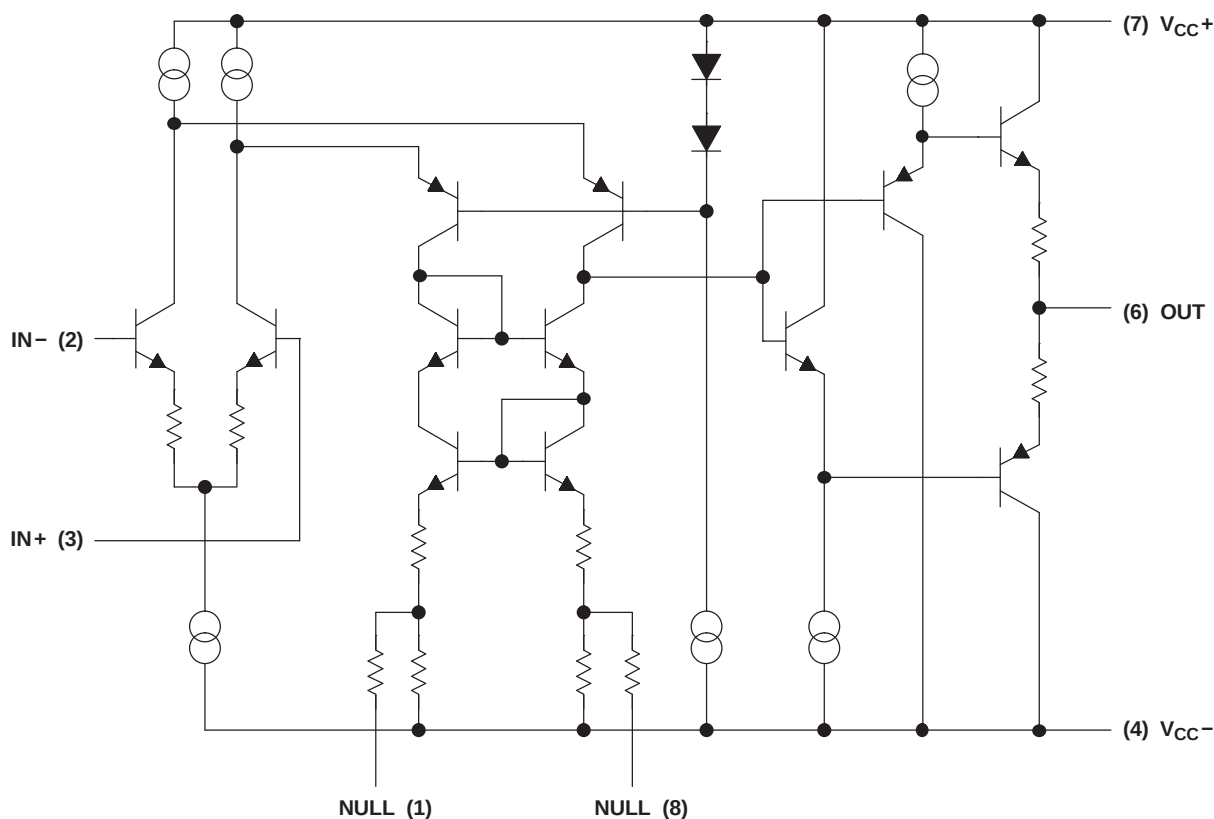


Figure 51. THS4031 Simplified Schematic

NOISE CALCULATIONS AND NOISE FIGURE

Noise can cause errors on very small signals. This is especially true when amplifying small signals. The noise model for the THS403x, shown in Figure 52, includes all of the noise sources as follows:

- e_n = Amplifier internal voltage noise ($\text{nV}/\sqrt{\text{Hz}}$)
- $\text{IN}+$ = Noninverting current noise ($\text{pA}/\sqrt{\text{Hz}}$)
- $\text{IN}-$ = Inverting current noise ($\text{pA}/\sqrt{\text{Hz}}$)
- e_{R_x} = Thermal voltage noise associated with each resistor ($e_{R_x} = 4 \text{ kTR}_x$)

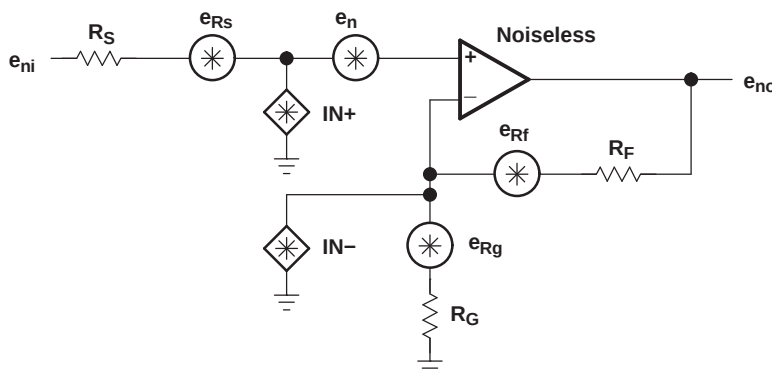


Figure 52. Noise Model

The total equivalent input noise density (e_{ni}) is calculated by using the following equation:

$$e_{ni} = \sqrt{(e_n)^2 + (\text{IN}+ \times R_S)^2 + (\text{IN}- \times (R_F \parallel R_G))^2 + 4 \text{ kTR}_S + 4 \text{ kT}(R_F \parallel R_G)}$$

Where:

k = Boltzmann's constant = 1.380658×10^{-23}

T = Temperature in degrees Kelvin ($273 + ^\circ\text{C}$)

$R_F \parallel R_G$ = Parallel resistance of R_F and R_G

(1)

To get the equivalent output noise of the amplifier, just multiply the equivalent input noise density (e_{ni}) by the overall amplifier gain (A_V).

$$e_{no} = e_{ni} A_V = e_{ni} \left(1 + \frac{R_F}{R_G} \right) \text{ (Noninverting Case)}$$

(2)

As the previous equations show, to keep noise at a minimum, small-value resistors should be used. As the closed-loop gain is increased (by reducing R_G), the input noise is reduced considerably because of the parallel resistance term. This leads to the general conclusion that the most dominant noise sources are the source resistor (R_S) and the internal amplifier noise voltage (e_n). Because noise is summed in a root-mean-squares method, noise sources smaller than 25% of the largest noise source can be effectively ignored. This advantage can greatly simplify the formula and make noise calculations much easier to calculate.

For more information on noise analysis, refer to the application note, *Noise Analysis for High-Speed Op Amps* (SBOA066).

OPTIMIZING FREQUENCY RESPONSE

Internal frequency compensation of the THS403x was selected to provide very wide bandwidth performance and still maintain a very low noise floor. In order to meet these performance requirements, the THS403x must have a minimum gain of 2 (–1). Because everything is referred to the noninverting terminal of an operational amplifier, the noise gain in a $G = -1$ configuration is the same as a $G = 2$ configuration.

One of the keys to maintaining a smooth frequency response, and hence, a stable pulse response, is to pay particular attention to the inverting terminal. Any stray capacitance at this node causes peaking in the frequency response (see Figure 53 and Figure 54). Two things can be done to help minimize this effect. The first is to simply remove any ground planes under the inverting terminal of the amplifier, including the trace that connects to this terminal. Additionally, the length of this trace should be minimized. The capacitance at this node causes a lag in the voltage being fed back due to the charging and discharging of the stray capacitance. If this lag becomes too long, the amplifier will not be able to correctly keep the noninverting terminal voltage at the same potential as the inverting terminal's voltage. Peaking and possible oscillations will then occur if this happens.

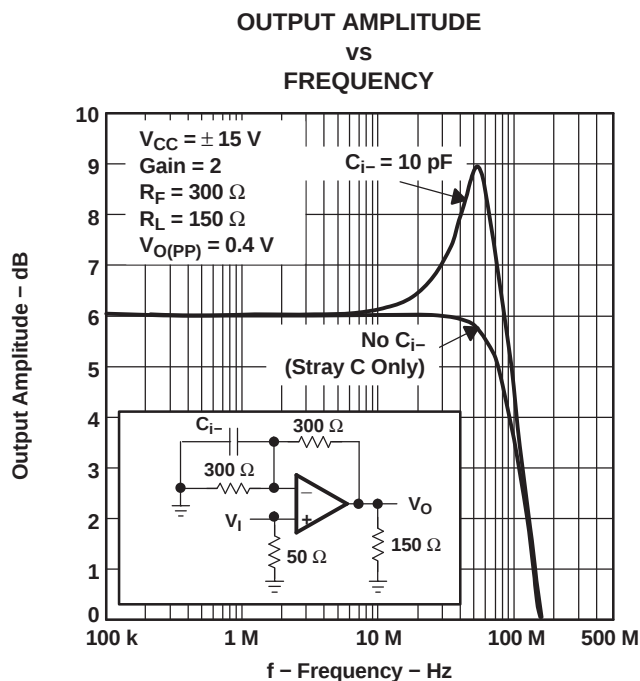


Figure 53.

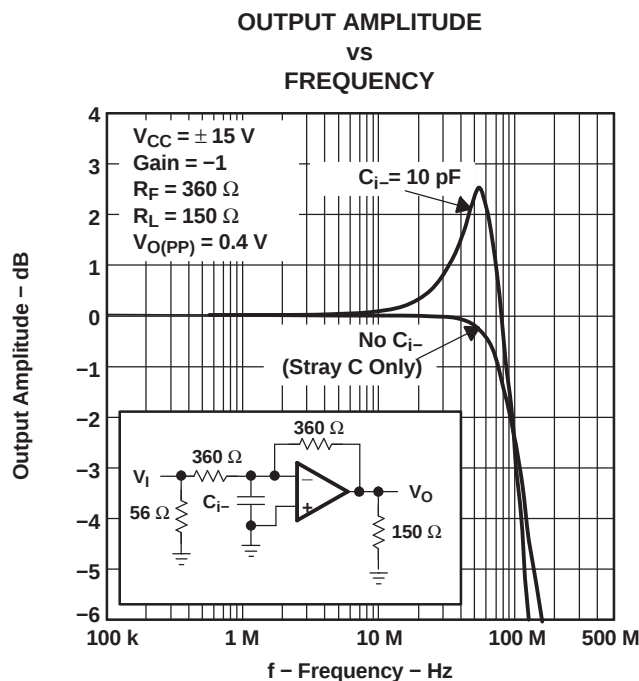


Figure 54.

The second precaution to help maintain a smooth frequency response is to keep the feedback resistor (R_F) and the gain resistor (R_G) values fairly low. These two resistors are effectively in parallel when looking at the ac small-signal response. But, as can be seen in Figure 26 through Figure 37, a value too low starts to reduce the bandwidth of the amplifier. Table 1 shows some recommended feedback resistors to be used with the THS403x.

Table 1. Recommended Feedback Resistors

GAIN	R_F for $V_{CC} = \pm 15\text{ V}$ and $\pm 5\text{ V}$
1	50 Ω
2	300 Ω
–1	360 Ω
5	3.3 k Ω (low stray-c PCB only)

DRIVING A CAPACITIVE LOAD

Driving capacitive loads with high-performance amplifiers is not a problem as long as certain precautions are taken. The first is to realize that the THS403x has been internally compensated to maximize its bandwidth and slew-rate performance. When the amplifier is compensated in this manner, capacitive loading directly on the output will decrease the phase margin of the device leading to high-frequency ringing or oscillations. Therefore, for capacitive loads of greater than 10 pF, it is recommended that a resistor be placed in series with the output of the amplifier, as shown in [Figure 55](#). A minimum value of 20 Ω should work well for most applications. For example, in 75- Ω transmission systems, setting the series resistor value to 75 Ω both isolates any capacitance loading and provides the proper line impedance matching at the source end.

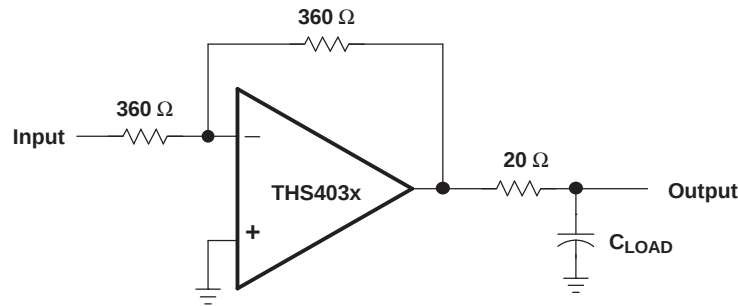


Figure 55. Driving a Capacitive Load

OFFSET NULLING

The THS403x has very low input offset voltage for a high speed amplifier. However, if additional correction is required, the designer can make use of an offset nulling function provided on the THS4031. By placing a potentiometer between terminals 1 and 8 of the device and tying the wiper to the negative supply, the input offset can be adjusted. This is shown in [Figure 56](#).

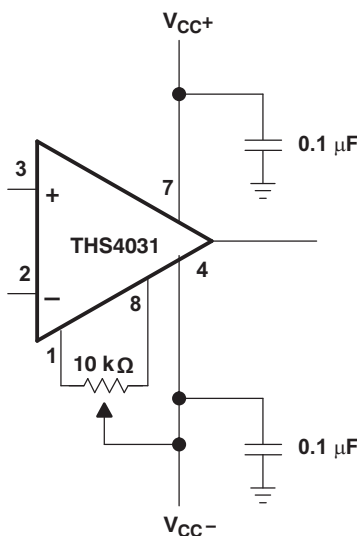
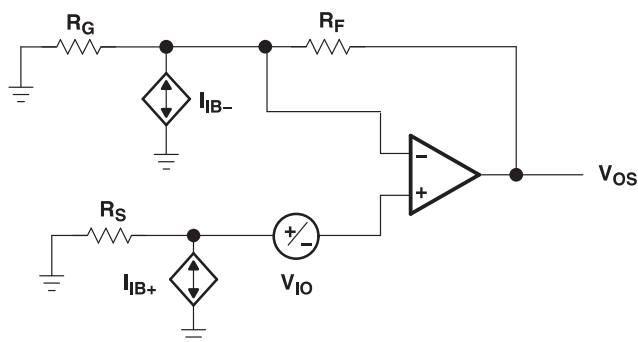


Figure 56. Offset Nulling Schematic

OFFSET VOLTAGE

The output offset voltage (V_{OO}) is the sum of the input offset voltage (V_{IO}) and both input bias currents (I_{IB}) times the corresponding gains. The following schematic and formula can be used to calculate the output offset voltage:



$$V_{OS} = (\pm V_{IO} \pm I_{IB+} R_S) \left(1 + \frac{R_F}{R_G} \right) \pm I_{IB-} R_F$$

Figure 57. Output Offset Voltage Model

GENERAL CONFIGURATIONS

When receiving low-level signals, limiting the bandwidth of the incoming signals into the system is often required. The simplest way to accomplish this is to place an RC filter at the noninverting terminal of the amplifier (see [Figure 58](#)).

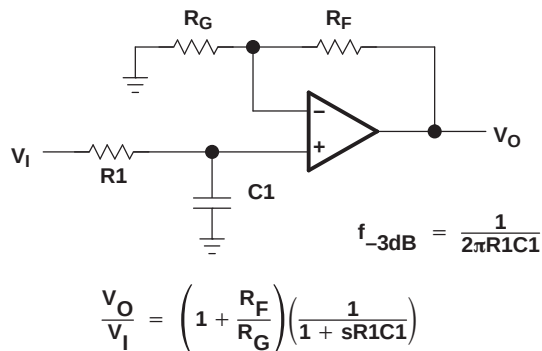


Figure 58. Single-Pole Low-Pass Filter

If even more attenuation is needed, a multiple-pole filter is required. The Sallen-Key filter can be used for this task. For best results, the amplifier should have a bandwidth that is 8 to 10 times the filter frequency bandwidth. Otherwise, phase shift of the amplifier can occur.

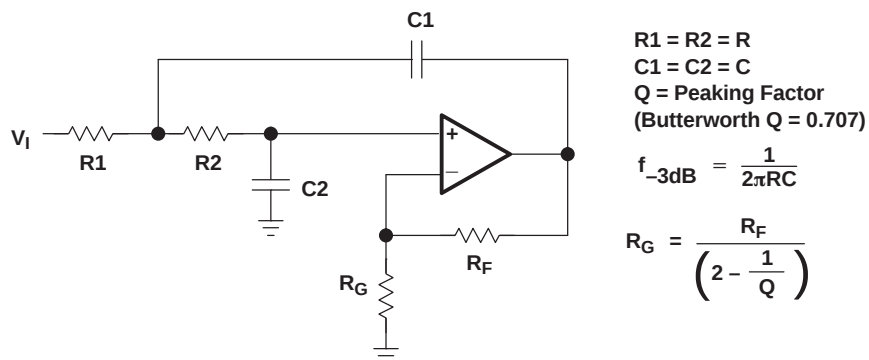


Figure 59. Two-Pole Low-Pass Sallen-Key Filter

CIRCUIT-LAYOUT CONSIDERATIONS

In order to achieve the levels of high-frequency performance of the THS403x, it is essential that proper printed-circuit board (PCB) high-frequency design techniques be followed. A general set of guidelines is given below. In addition, a THS403x evaluation board is available to use as a guide for layout or for evaluating the device performance.

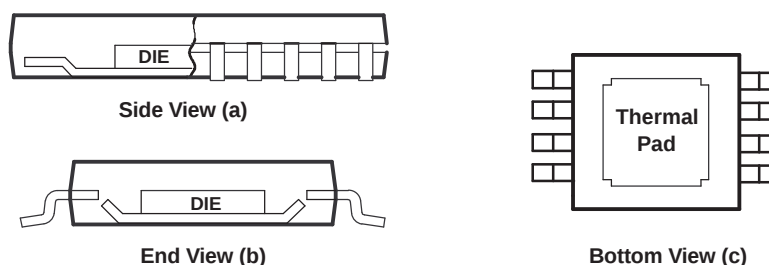
- **Ground planes:** It is highly recommended that a ground plane be used on the board to provide all components with a low inductive ground connection. However, in the areas of the amplifier inputs and output, the ground plane can be removed to minimize the stray capacitance.
- **Proper power-supply decoupling:** Use a 6.8- μ F tantalum capacitor in parallel with a 0.1- μ F ceramic capacitor on each supply terminal. It may be possible to share the tantalum among several amplifiers depending on the application, but a 0.1- μ F ceramic capacitor should always be used on the supply terminal of every amplifier. In addition, the 0.1- μ F capacitor should be placed as close as possible to the supply terminal. As this distance increases, the inductance in the connecting trace makes the capacitor less effective. The designer should strive for distances of less than 0.1 inch between the device power terminals and the ceramic capacitors.
- **Sockets:** Sockets are not recommended for high-speed operational amplifiers. The additional lead inductance in the socket pins will often lead to stability problems. Surface-mount packages soldered directly to the printed-circuit board is the best implementation.
- **Short trace runs/compact part placements:** Optimum high-frequency performance is achieved when stray series inductance has been minimized. To realize this, the circuit layout should be made as compact as possible, thereby minimizing the length of all trace runs. Particular attention should be paid to the inverting input of the amplifier. Its length should be kept as short as possible. This will help to minimize stray capacitance at the input of the amplifier.
- **Surface-mount passive components:** Using surface-mount passive components is recommended for high-frequency amplifier circuits for several reasons. First, because of the extremely low lead inductance of surface-mount components, the problem with stray series inductance is greatly reduced. Second, the small size of surface-mount components naturally leads to a more compact layout thereby minimizing both stray inductance and capacitance. If leaded components are used, it is recommended that the lead lengths be kept as short as possible.

GENERAL PowerPAD™ DESIGN CONSIDERATIONS

The THS403x is available in a thermally-enhanced DGN package, which is a member of the PowerPAD family of packages. This package is constructed using a downset leadframe upon which the die is mounted [see [Figure 60\(a\)](#) and [Figure 60\(b\)](#)]. This arrangement results in the leadframe being exposed as a thermal pad on the underside of the package [see [Figure 60\(c\)](#)]. Because this thermal pad has direct thermal contact with the die, excellent thermal performance can be achieved by providing a good thermal path away from the thermal pad.

The PowerPAD package allows for both assembly and thermal management in one manufacturing operation. During the surface-mount solder operation (when the leads are being soldered), the thermal pad can also be soldered to a copper area underneath the package. Through the use of thermal paths within this copper area, heat can be conducted away from the package into either a ground plane or other heat-dissipating device.

The PowerPAD package represents a breakthrough in combining the small area and ease of assembly of surface mount with the heretofore awkward mechanical methods of heatsinking.



- A. The thermal pad is electrically isolated from all terminals in the package.

Figure 60. Views of Thermally-Enhanced DGN Package

Although there are many ways to properly heatsink this device, the following steps illustrate the recommended approach.

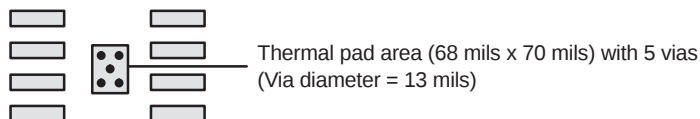


Figure 61. PowerPAD™ PCB Etch and Via Pattern

1. Prepare the PCB with a top-side etch pattern as shown in [Figure 61](#). There should be etch for the leads as well as etch for the thermal pad.
2. Place five holes in the area of the thermal pad. These holes should be 13 mils (0,3302 mm) in diameter. They are kept small so that solder wicking through the holes is not a problem during reflow.
3. Additional vias may be placed anywhere along the thermal plane outside of the thermal pad area. This helps dissipate the heat generated by the THS403xDGN IC. These additional vias may be larger than the 13-mil diameter vias directly under the thermal pad. They can be larger because they are not in the thermal pad area to be soldered so that wicking is not a problem.
4. Connect all holes to the internal ground plane.
5. When connecting these holes to the ground plane, *do not* use the typical web or spoke via connection methodology. Web connections have a high thermal-resistance connection that is useful for slowing the heat transfer during soldering operations. This makes the soldering of vias that have plane connections easier. In this application, however, low thermal resistance is desired for the most efficient heat transfer. Therefore, the holes under the THS403xDGN package should connect to the internal ground plane with a complete connection around the entire circumference of the plated-through hole.
6. The top-side solder mask should leave the terminals of the package and the thermal pad area with its five holes exposed. The bottom-side solder mask should cover the five holes of the thermal pad area, which prevents solder from being pulled away from the thermal pad area during the reflow process.
7. Apply solder paste to the exposed thermal pad area and to all the IC terminals.
8. With these preparatory steps in place, the THS403xDGN IC is simply placed in position and run through the solder reflow operation as any standard surface-mount component. This results in a part that is properly installed.

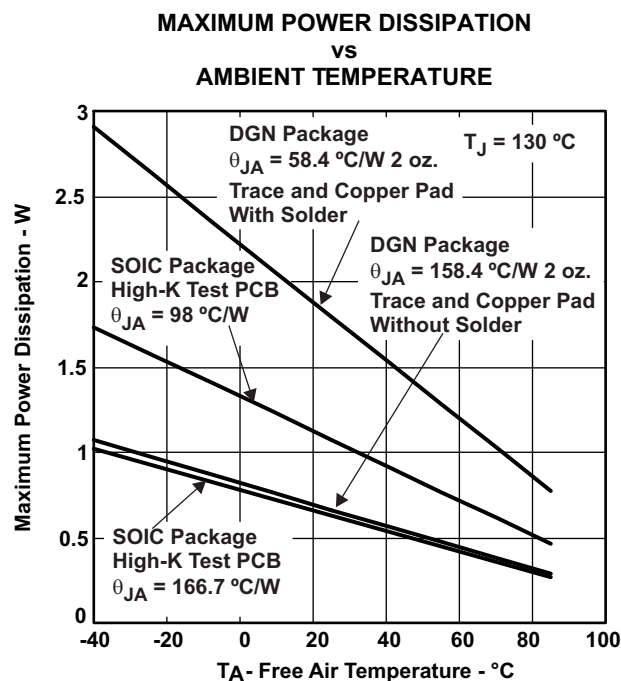
The actual thermal performance achieved with the THS403xDGN in its PowerPAD™ package depends on the application. In the example above, if the size of the internal ground plane is approximately 3 inches × 3 inches (7,62 cm × 7,62 cm), then the expected thermal coefficient, θ_{JA} , is about 58.4°C/W. For comparison, the non-PowerPAD™ version of the THS403x IC (SOIC) is shown. For a given θ_{JA} , the maximum power dissipation is shown in Figure 62 and is calculated by the following formula:

$$P_D = \left(\frac{T_{MAX} - T_A}{\theta_{JA}} \right)$$

Where:

- P_D = Maximum power dissipation of THS403x IC (watts)
- T_{MAX} = Absolute maximum operating junction temperature (125°C)
- T_A = Free-ambient air temperature (°C)
- $\theta_{JA} = \theta_{JC} + \theta_{CA}$
 - θ_{JC} = Thermal coefficient from junction to case
 - θ_{CA} = Thermal coefficient from case to ambient air (°C/W)

(3)



Results are with no air flow and PCB size = 3" × 3" (7,62 cm × 7,62 cm)

Figure 62. Maximum Power Dissipation vs Free-Air Temperature

More complete details of the PowerPAD installation process and thermal management techniques can be found in the Texas Instruments technical brief, *PowerPAD™ Thermally-Enhanced Package* (SLMA002). This document can be found at the TI web site (www.ti.com) by searching on the key word PowerPAD. The document can also be ordered through your local TI sales office. Refer to literature number SLMA002 when ordering.

The next thing to be considered is package constraints. The two sources of heat within an amplifier are quiescent power and output power. The designer should never forget about the quiescent heat generated within the device, especially multi-amplifier devices. Because these devices have linear output stages (Class A-B), most of the heat dissipation is at low output voltages with high output currents. Figure 63 to Figure 66 shows this effect, along with the quiescent heat, with an ambient air temperature of 50°C. When using $V_{CC} = \pm 5$ V, heat is generally not a problem, even with SOIC packages. But, when using $V_{CC} = \pm 15$ V, the SOIC package is severely limited in the amount of heat it can dissipate. The other key factor when looking at these graphs is how the devices are mounted on the PCB. The PowerPAD™ devices are extremely useful for heat dissipation. But, the device should

always be soldered to a copper plane to fully use the heat dissipation properties of the PowerPAD™. The SOIC package, on the other hand, is highly dependent on how it is mounted on the PCB. As more trace and copper area is placed around the device, θ_{JA} decreases and the heat dissipation capability increases. The currents and voltages shown in these graphs are for the total package. For the dual amplifier package (THS4032), the sum of the RMS output currents and voltages should be used to choose the proper package.

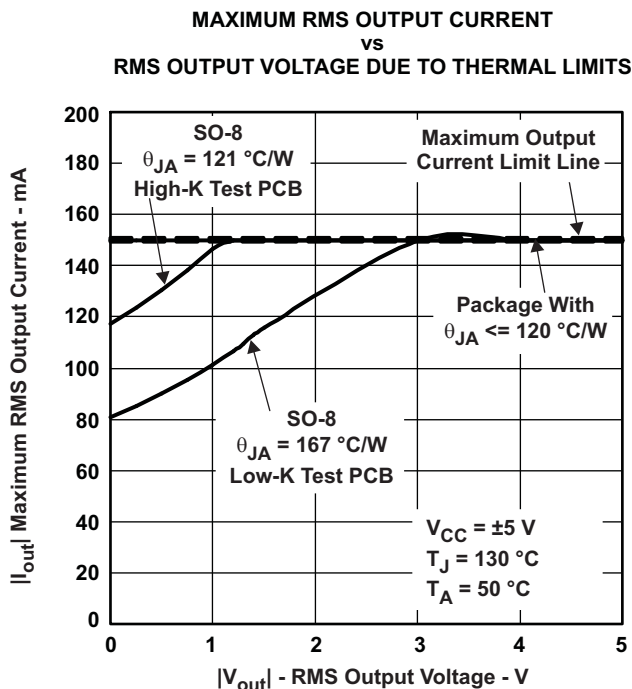


Figure 63.

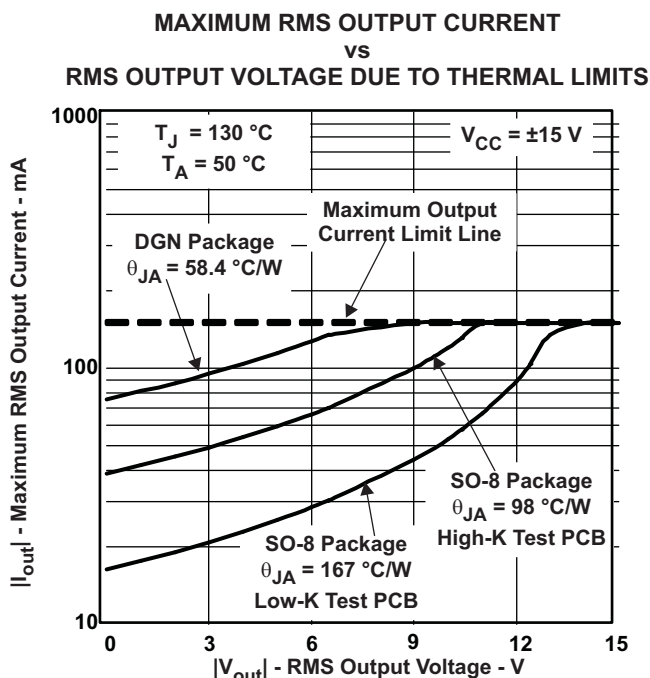


Figure 64.

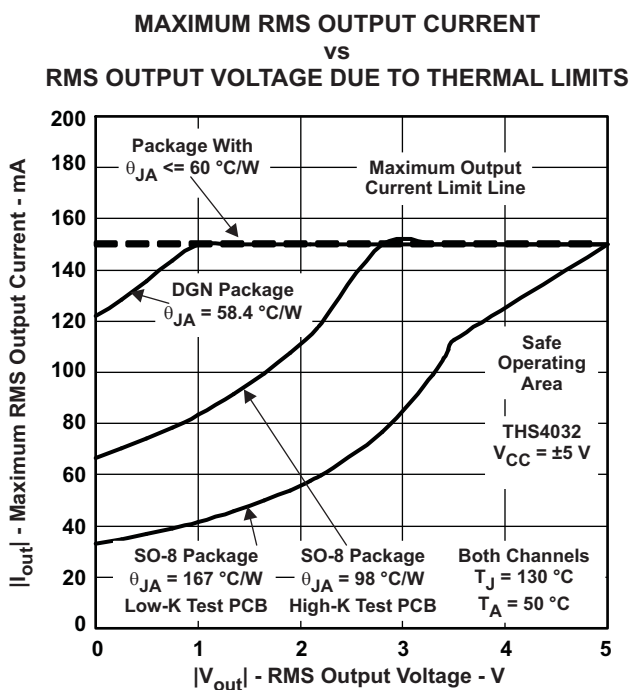


Figure 65.

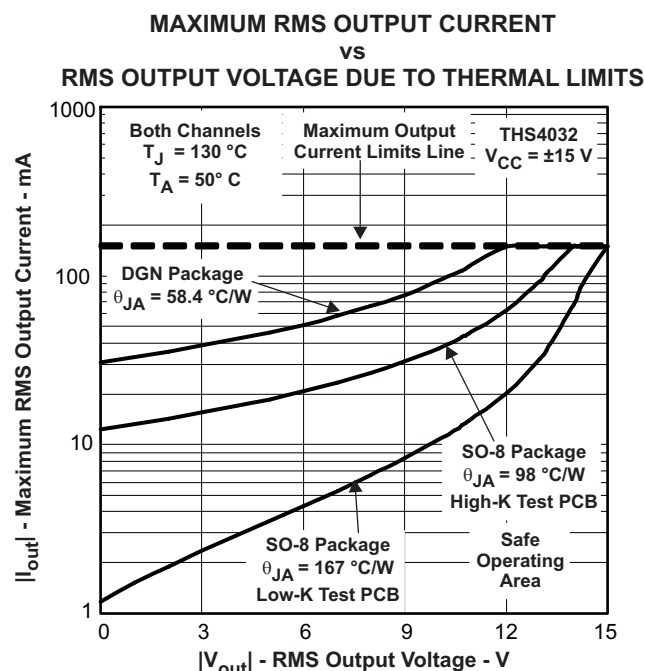


Figure 66.

EVALUATION BOARD

An evaluation board is available for the THS4031 (literature number [SLOP203](#)) and THS4032 (literature number [SLOP135](#)). This board has been configured for very low parasitic capacitance in order to realize the full performance of the amplifier. A schematic of the evaluation board is shown in [Figure 67](#). The circuitry has been designed so that the amplifier may be used in either an inverting or noninverting configuration. For more information, refer to the *THS4031 EVM User's Guide* ([SLOU038](#)) or the *THS4032 EVM User's Guide* ([SLOU039](#)). To order the evaluation board, contact your local TI sales office or distributor.

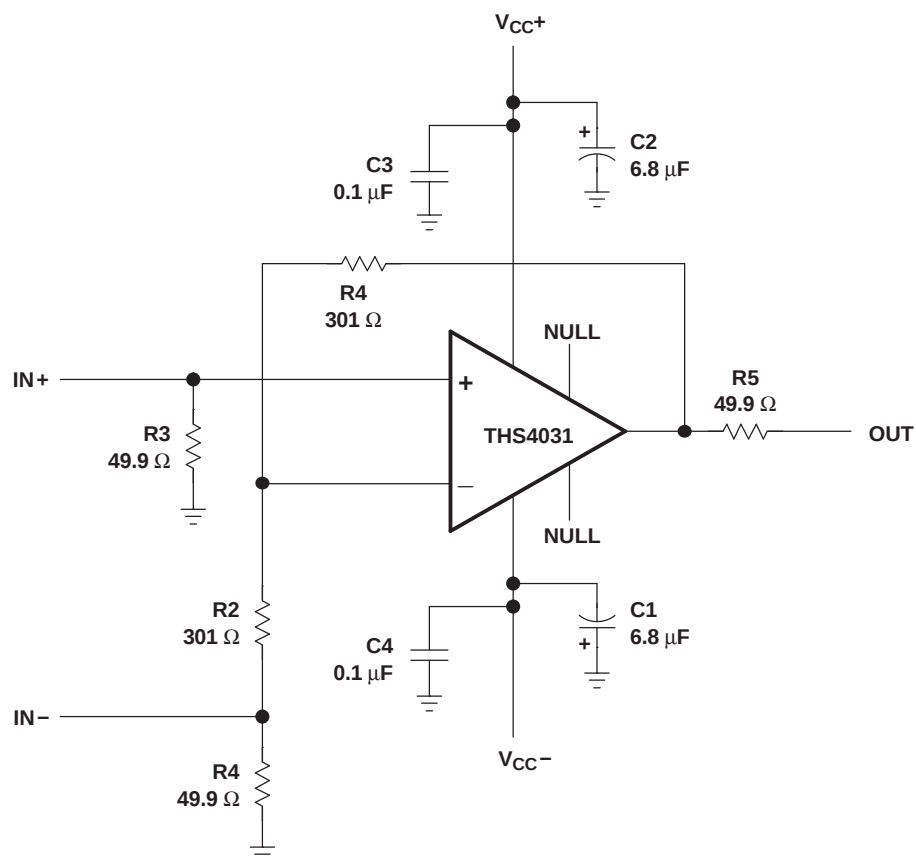


Figure 67. THS4031 Evaluation Board

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
5962-9959501Q2A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9959501Q2A THS4031MFKB
5962-9959501QPA	Active	Production	CDIP (JG) 8	50 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9959501QPA THS4031M
THS4031MFKB	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9959501Q2A THS4031MFKB
THS4031MFKB.A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9959501Q2A THS4031MFKB
THS4031MJG	Active	Production	CDIP (JG) 8	50 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	THS4031MJG
THS4031MJG.A	Active	Production	CDIP (JG) 8	50 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	THS4031MJG
THS4031MJGB	Active	Production	CDIP (JG) 8	50 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9959501QPA THS4031M
THS4031MJGB.A	Active	Production	CDIP (JG) 8	50 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9959501QPA THS4031M
THS4032MDGNREP	Active	Production	HVSSOP (DGN) 8	2500 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-55 to 125	NXX
THS4032MDGNREP.A	Active	Production	HVSSOP (DGN) 8	2500 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-55 to 125	NXX
V62/09612-01XE	Active	Production	HVSSOP (DGN) 8	2500 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-55 to 125	NXX

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF THS4031M, THS4032-EP :

- Catalog : [THS4031](#), [THS4032](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
THS4032MDGNREP	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
THS4032MDGNREP	HVSSOP	DGN	8	2500	358.0	335.0	35.0

TUBE

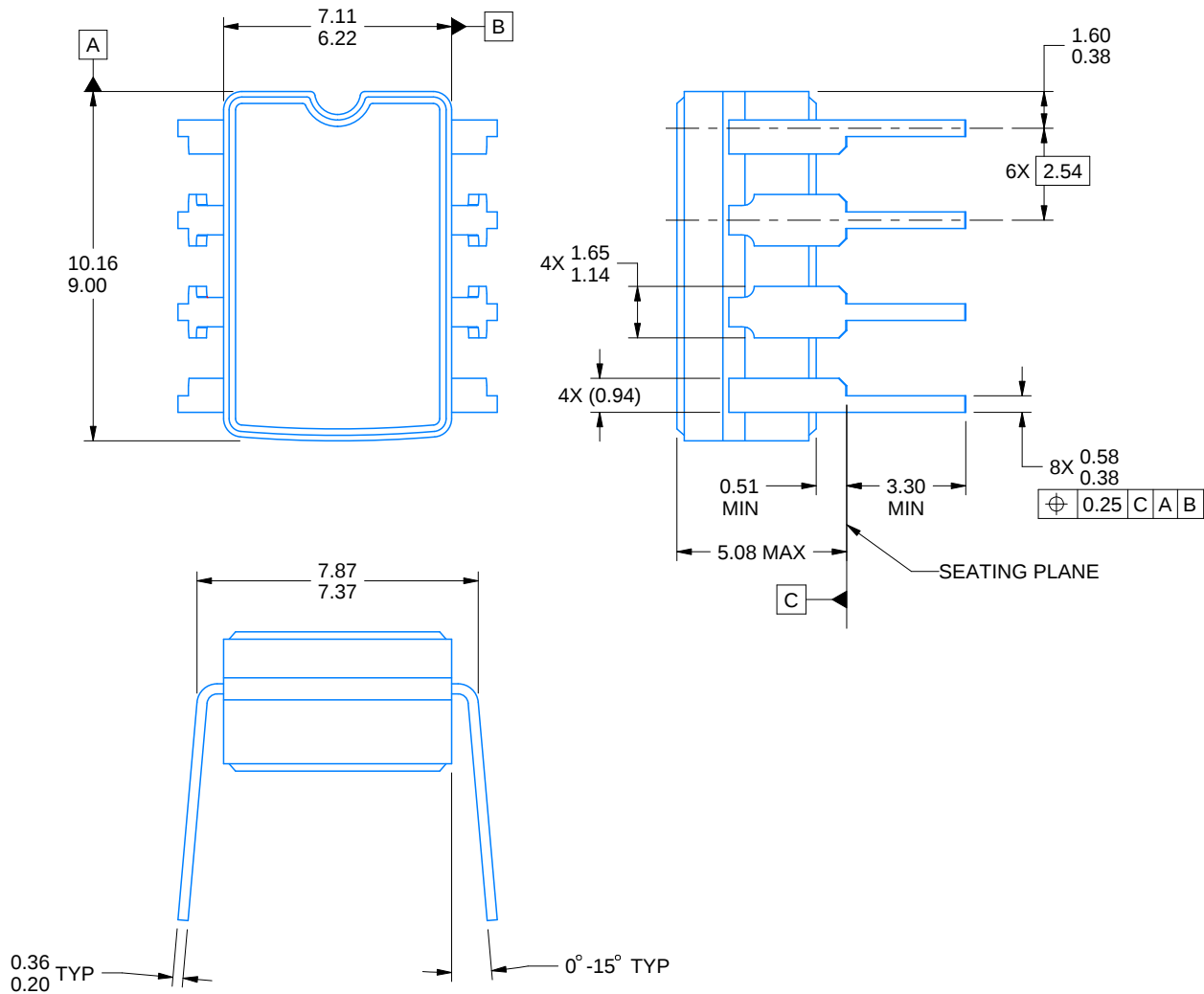


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
5962-9959501Q2A	FK	LCCC	20	55	506.98	12.06	2030	NA
THS4031MFKB	FK	LCCC	20	55	506.98	12.06	2030	NA
THS4031MFKB.A	FK	LCCC	20	55	506.98	12.06	2030	NA

JG0008A**PACKAGE OUTLINE****CDIP - 5.08 mm max height**

CERAMIC DUAL IN-LINE PACKAGE



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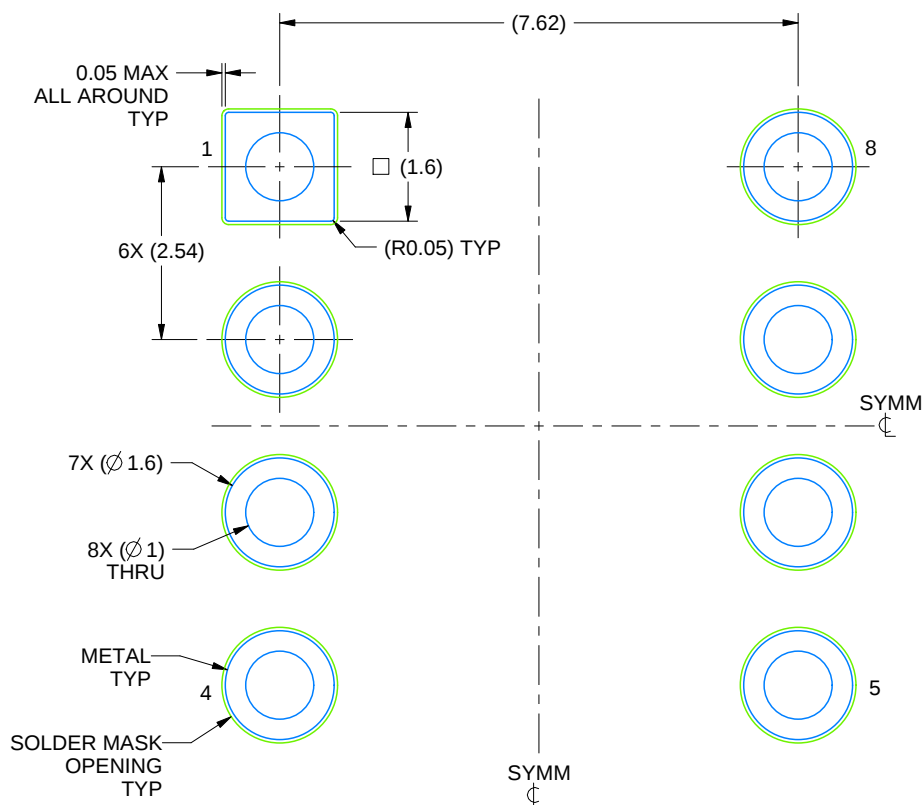
NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This package can be hermetically sealed with a ceramic lid using glass frit.
4. Index point is provided on cap for terminal identification.
5. Falls within MIL STD 1835 GDIP1-T8

JG0008A

CDIP - 5.08 mm max height

CERAMIC DUAL IN-LINE PACKAGE



LAND PATTERN EXAMPLE
NON SOLDER MASK DEFINED
SCALE: 9X

4230036/A 09/2023

GENERIC PACKAGE VIEW

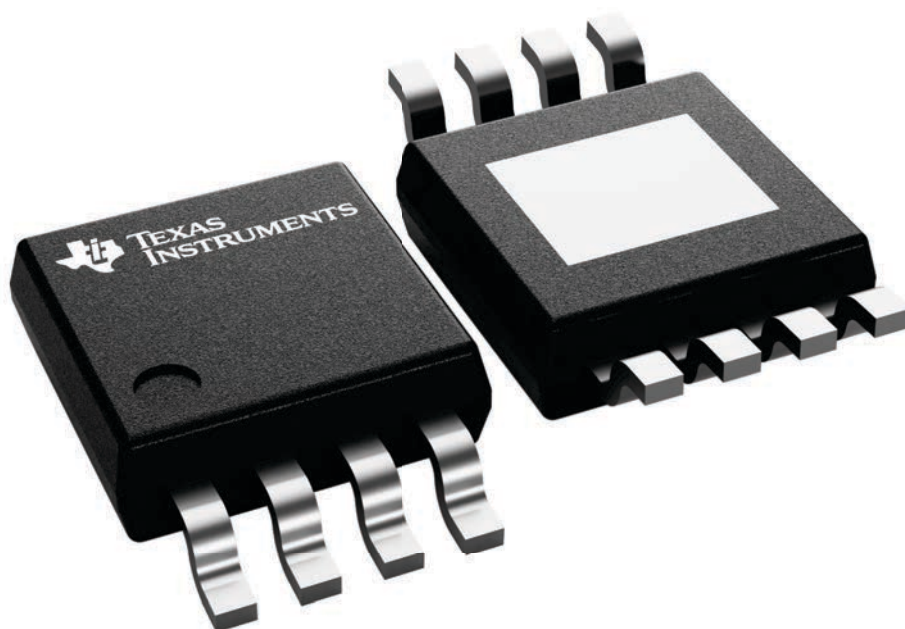
DGN 8

PowerPAD™ HVSSOP - 1.1 mm max height

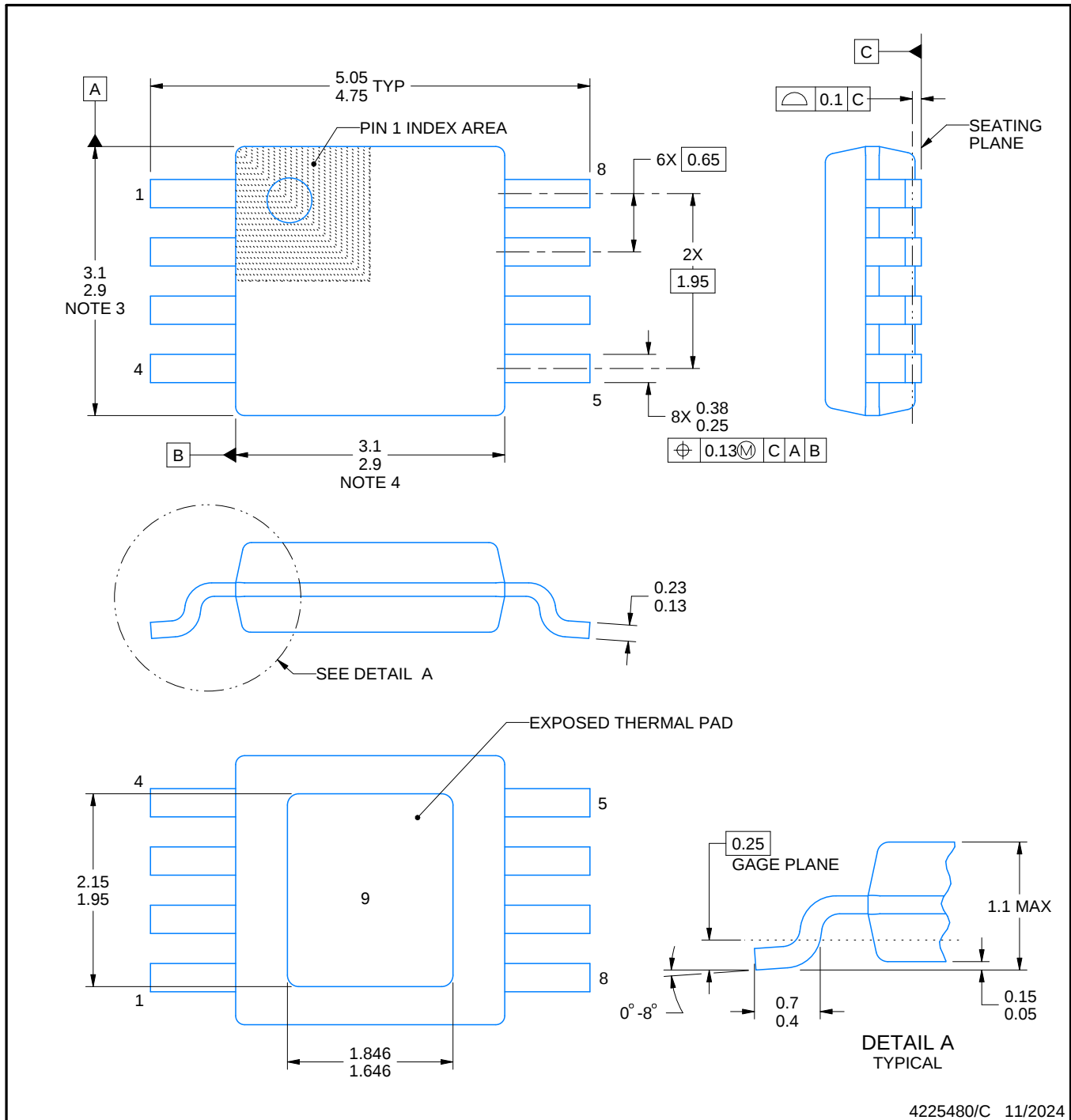
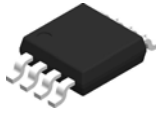
3 x 3, 0.65 mm pitch

SMALL OUTLINE PACKAGE

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



4225482/B



4225480/C 11/2024

NOTES:

PowerPAD is a trademark of Texas Instruments.

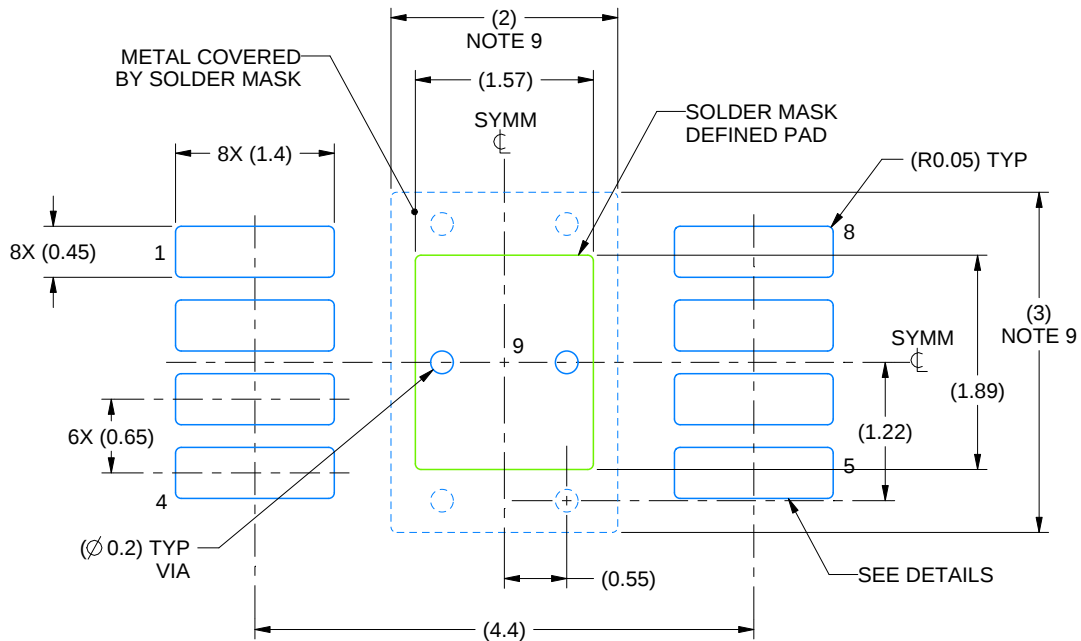
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

EXAMPLE BOARD LAYOUT

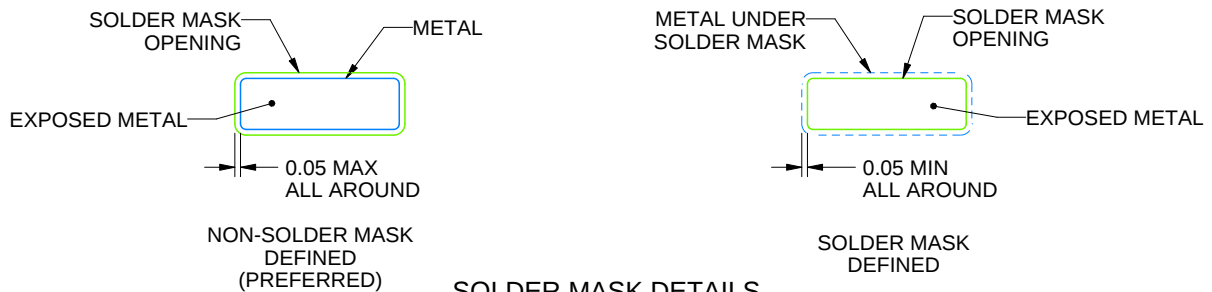
DGN0008G

PowerPAD™ HVSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X



SOLDER MASK DETAILS

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NOTES: (continued)

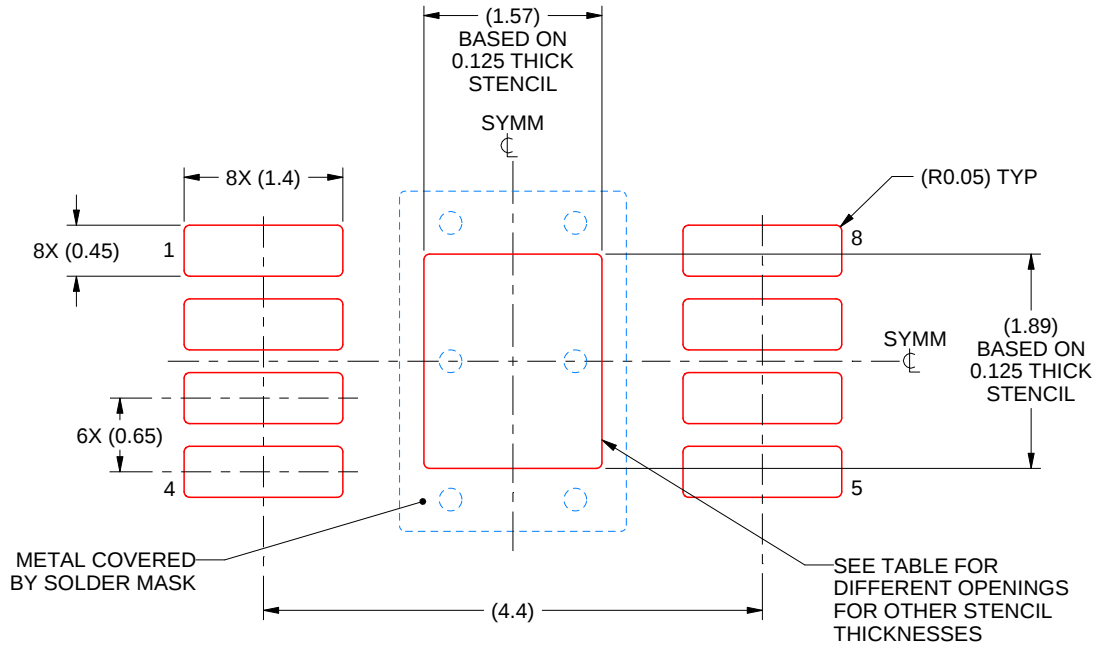
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

EXAMPLE STENCIL DESIGN

DGN0008G

PowerPAD™ HVSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
EXPOSED PAD 9:
100% PRINTED SOLDER COVERAGE BY AREA
SCALE: 15X

STENCIL THICKNESS	SOLDER STENCIL OPENING
0.1	1.76 X 2.11
0.125	1.57 X 1.89 (SHOWN)
0.15	1.43 X 1.73
0.175	1.33 X 1.60

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NOTES: (continued)

10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
11. Board assembly site may have different recommendations for stencil design.

GENERIC PACKAGE VIEW

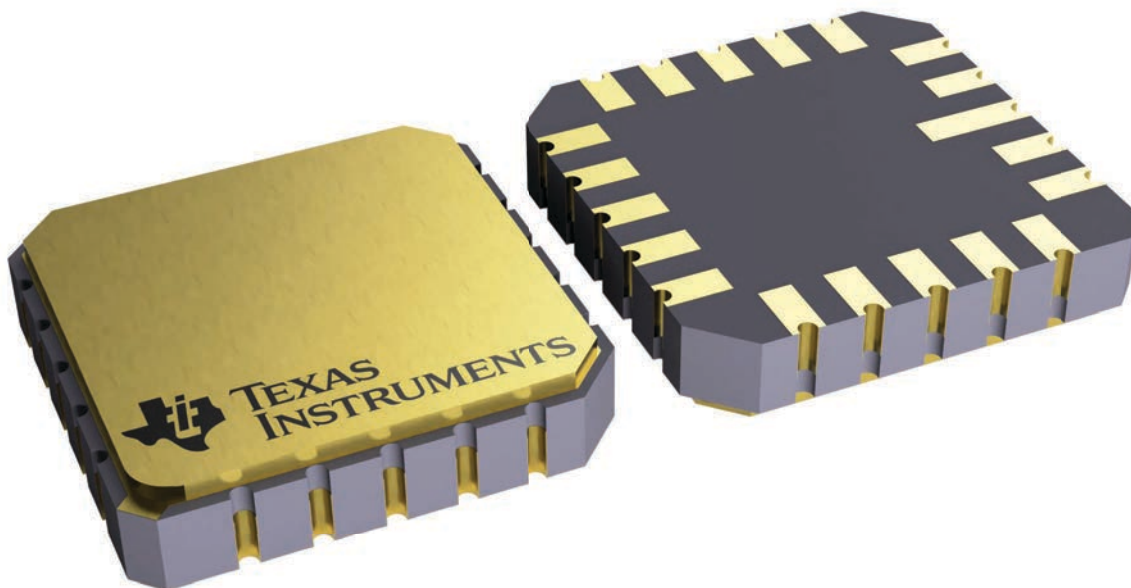
FK 20

LCCC - 2.03 mm max height

8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



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